## TLE202x, TLE202xA, TLE202xB, TLE202xY EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

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- Supply Current . . . 300 μA Max
- High Unity-Gain Bandwidth . . . 2 MHz Typ
- High Slew Rate . . . 0.45 V/μs Min
- Supply-Current Change Over Military Temp Range . . . 10  $\mu$ A Typ at  $V_{CC\pm} = \pm$  15 V
- Specified for Both 5-V Single-Supply and ±15-V Operation
- Phase-Reversal Protection

- High Open-Loop Gain . . . 6.5 V/μV (136 dB) Typ
- Low Offset Voltage . . . 100 μV Max
- Offset Voltage Drift With Time 0.005 μV/mo Typ
- Low Input Bias Current . . . 50 nA Max
- Low Noise Voltage . . . 19 nV/√Hz Typ

### description

The TLE202xA, TLE202xA, and TLE202xB devices are precision, high-speed, low-power operational amplifiers using a new Texas Instruments Excalibur process. These devices combine the best features of the OP21 with highly improved slew rate and unity-gain bandwidth.

The complementary bipolar Excalibur process utilizes isolated vertical pnp transistors that yield dramatic improvement in unity-gain bandwidth and slew rate over similar devices.

The addition of a bias circuit in conjunction with this process results in extremely stable parameters with both time and temperature. This means that a precision device remains a precision device even with changes in temperature and over years of use.

This combination of excellent dc performance with a common-mode input voltage range that includes the negative rail makes these devices the ideal choice for low-level signal conditioning applications in either single-supply or split-supply configurations. In addition, these devices offer phase-reversal protection circuitry that eliminates an unexpected change in output states when one of the inputs goes below the negative supply rail.

A variety of available options includes small-outline and chip-carrier versions for high-density systems applications.

The C-suffix devices are characterized for operation from  $0^{\circ}$ C to  $70^{\circ}$ C. The I-suffix devices are characterized for operation from  $-40^{\circ}$ C to  $85^{\circ}$ C. The M-suffix devices are characterized for operation over the full military temperature range of  $-55^{\circ}$ C to  $125^{\circ}$ C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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# TLE202xA, TLE202xB, TLE202xY EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

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#### **TLE2021 AVAILABLE OPTIONS**

				PACKAGEI	D DEVICES			
TA	V <sub>IO</sub> max AT 25°C	SMALL OUTLINE <sup>†</sup> (D)	SSOP <sup>‡</sup> (DB)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	TSSOP <sup>‡</sup> (PW)	CHIP FORM <sup>§</sup> (Y)
0°C to 70°C	200 μV 500 μV	TLE2021ACD TLE2021CD	TLE2021CDBLE	_	_	TLE2021ACP TLE2021CP	 TLE2021CPWLE	— TLE2021Y
-40°C to 85°C	200 μV 500 μV	TLE2021AID TLE2021ID	_		_	TLE2021AIP TLE2021IP		_
-55°C to 125°C	100 μV 500 μV	TLE2021MD	_	TLE2021BMFK TLE2021MFK	TLE2021BMJG TLE2021MJG	TLE2021MP	_	_

<sup>†</sup> The D packages are available taped and reeled. To order a taped and reeled part, add the suffix R (e.g., TLE2021CDR).

#### **TLE2022 AVAILABLE OPTIONS**

				PACKAGE	D DEVICES			
TA	V <sub>IO</sub> max AT 25°C	SMALL OUTLINE <sup>†</sup> (D)	SSOP <sup>‡</sup> (DB)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	TSSOP <sup>‡</sup> (PW)	CHIP FORM <sup>§</sup> (Y)
0°C to 70°C	150 μV 300 μV 500 μV	TLE2022BCD TLE2022ACD TLE2022CD	— TLE2022CDBLE	_	_	TLE2022ACP	— — TLE2022CPWLE	  TLE2022Y
-40°C to 85°C	150 μV 300 μV 500 μV	TLE2022BID TLE2022AID TLE2022ID	_	_	_	TLE2022AIP TLE2022IP	_	_
-55°C to 125°C	150 μV 300 μV 500 μV	TLE2022AMD TLE2022MD	_	TLE2022AMFK TLE2022MFK	TLE2022BMJG TLE2022AMJG TLE2022MJG	 TLE2022AMP TLE2022MP	_	_

<sup>†</sup> The D packages are available taped and reeled. To order a taped and reeled part, add the suffix R (e.g., TLE2022CDR).

#### **TLE2024 AVAILABLE OPTIONS**

			PACKAGED	DEVICES		CLUD
T <sub>A</sub>	V <sub>IO</sub> max AT 25°C	SMALL OUTLINE (DW)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)	CHIP FORM <sup>§</sup> (Y)
0°C to 70°C	500 μV 750 μV 1000 μV	TLE2024BCDW TLE2024ACDW TLE2024CDW	l		TLE2024BCN TLE2024ACN TLE2024CN	  TLE2024Y
-40°C to 85°C	500 μV 750 μV 1000 μV	TLE2024BIDW TLE2024AIDW TLE2024IDW			TLE2024BIN TLE2024AIN TLE2024IN	
-55°C to 125°C	500 μV 750 μV 1000 μV	TLE2024BMDW TLE2024AMDW TLE2024MDW	TLE2024BMFK TLE2024AMFK TLE2024MFK	TLE2024BMJ TLE2024AMJ TLE2024MJ	TLE2024BMN TLE2024AMN TLE2024MN	

<sup>§</sup> Chip forms are tested at 25°C only.



<sup>&</sup>lt;sup>‡</sup> The DB and PW packages are only available left-end taped and reeled.

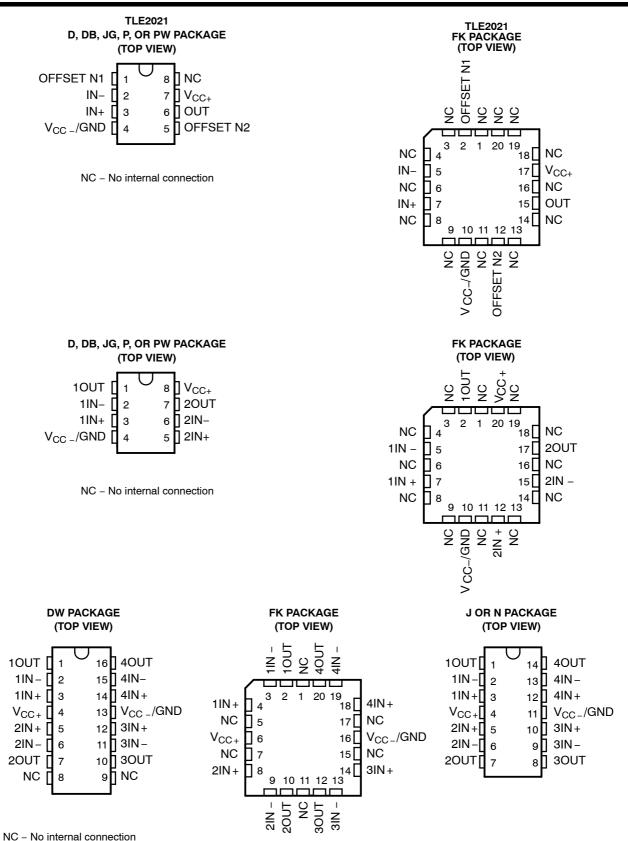
<sup>§</sup> Chip forms are tested at 25°C only.

<sup>&</sup>lt;sup>‡</sup> The DB and PW packages are only available left-end taped and reeled.

<sup>§</sup> Chip forms are tested at 25°C only.

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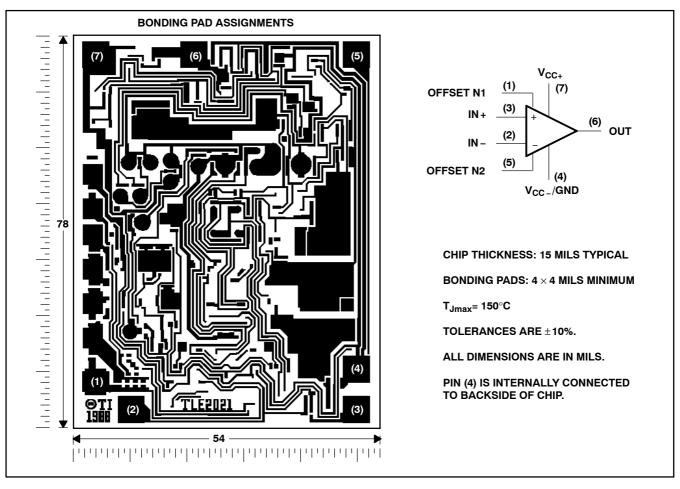


# TLE202xA, TLE202xB, TLE202xY EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

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### **TLE2021Y chip information**

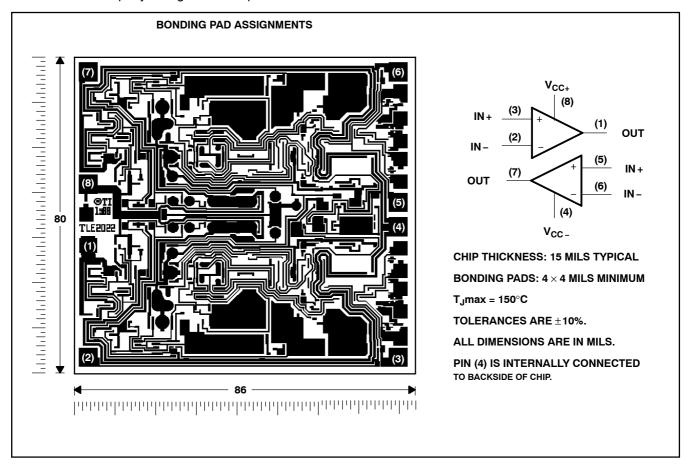
This chip, when properly assembled, display characteristics similar to the TLE2021. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. This chip may be mounted with conductive epoxy or a gold-silicon preform.



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### **TLE2022Y chip information**

This chip, when properly assembled, displays characteristics similar to TLE2022. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. This chip may be mounted with conductive epoxy or a gold-silicon preform.

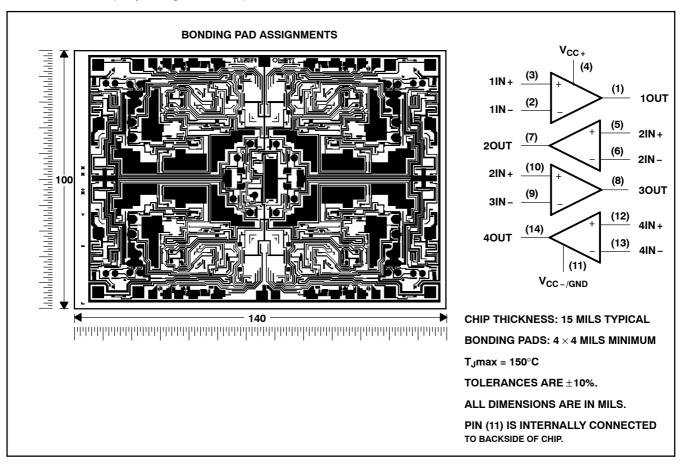


# TLE202xA, TLE202xB, TLE202xY EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

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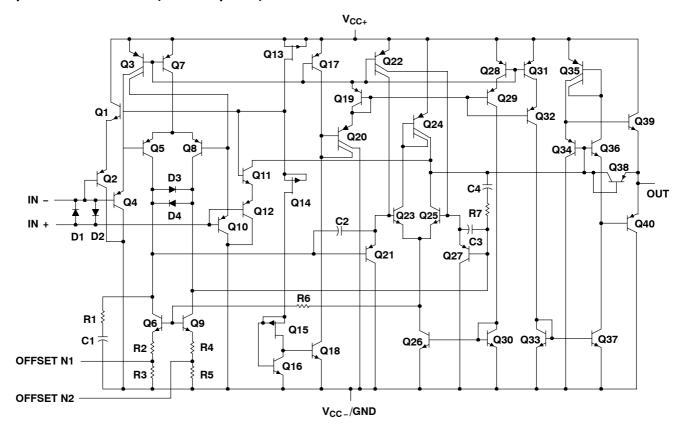
### **TLE2024Y chip information**

This chip, when properly assembled, displays characteristics similar to the TLE2024. Thermal compression or ultrasonic bonding may be used on the doped aluminum-bonding pads. This chip may be mounted with conductive epoxy or a gold-silicon preform.



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## equivalent schematic (each amplifier)



ACTU	ACTUAL DEVICE COMPONENT COUNT												
COMPONENT	TLE2021	TLE2022	TLE2024										
Transistors	40	80	160										
Resistors	7	14	28										
Diodes	4	8	16										
Capacitors 4 8 16													

# TLE202xA, TLE202xB, TLE202xY EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V <sub>CC+</sub> (see Note 1)	
Supply voltage, V <sub>CC</sub> (see Note 1)	
Differential input voltage, V <sub>ID</sub> (see Note 2)	
Input voltage range, V <sub>I</sub> (any input, see Note 1)	
Input current, I <sub>I</sub> (each input)	±1 mA
Output current, I <sub>O</sub> (each output): TLE2021	±20 mA
TLE2022	±30 mA
TLE2024	±40 mA
Total current into V <sub>CC+</sub>	80 mA
Total current out of V <sub>CC</sub>	80 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T <sub>A</sub> : C suffix	0°C to 70°C
I suffix	–40°C to 85°C
M suffix	–55°C to 125°C
Storage temperature range, T <sub>stq</sub>	–65°C to 150°C
Case temperature for 60 seconds, T <sub>C</sub> : FK package	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D, DP, P, or P	
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: JG package	300°C

<sup>&</sup>lt;sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V<sub>CC+</sub>, and V<sub>CC-</sub>.
  - Differential voltages are at IN+ with respect to IN -. Excessive current flows if a differential input voltage in excess of approximately ±600 mV is applied between the inputs unless some limiting resistance is used.
  - 3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

### **DISSIPATION RATING TABLE**

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING	T <sub>A</sub> = 125°C POWER RATING
D-8	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW
DB-8	525 mW	4.2 mW/°C	336 mW	_	_
DW-16	1025 mW	8.2 mW/°C	656 mW	533 mW	205 mW
FK	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW
J-14	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW
JG-8	1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW
N-14	1150 mW	9.2 mW/°C	736 mW	598 mW	230 mW
P-8	1000 mW	8.0 mW/°C	640 mW	520 mW	200 mW
PW-8	525 mW	4.2 mW/°C	336 mW	_	_

#### recommended operating conditions

		C SU	FFIX	I SUF	FIX	M SU	UNIT	
		MIN	MAX	MIN	MAX	MIN	MAX	UNII
Supply voltage, V <sub>CC</sub>		±2	±20	±2	±20	±2	±20	V
Common mode in a desirable of M	$V_{CC} = \pm 5 V$	0	3.5	0	3.2	0	3.2	V
Common-mode input voltage, V <sub>IC</sub>	$V_{CC\pm} = \pm 15 \text{ V}$	-15	13.5	-15	13.2	-15	13.2	V
Operating free-air temperature, T <sub>A</sub>		0	70	-40	85	-55	125	°C



## TLE2021 electrical characteristics at specified free-air temperature, V<sub>CC</sub> = 5 V (unless otherwise noted)

DADAMETED	TEGT COMPITIONS	<b>-</b> +	TI	_E20210		TL	E2021A	С	TL	E2021B	С	UNIT	
PARAMETER	TEST CONDITIONS	IA'	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNII	
Input offeet voltage		25°C		120	600		100	300		80	200	μV	
		Full range			850			600			300	μv	
Temperature coefficient of input offset voltage		Full range		2			2			2		μV/°C	
Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0$ , $R_S = 50 \Omega$	25°C		0.005			0.005			0.005		μV/mo	
land official and a		25°C		0.2	6		0.2	6		0.2	6	- 0	
input offset current		Full range			10			10			10	nA	
Innut bigg growent		25°C		25	70		25	70		25	70	nA	
Input bias current		Full range			90			90			90	ΠA	
		25°C	0 to	– 0.3 to		0 to	- 0.3 to		0 to	– 0.3 to			
Common-mode input voltage range	R <sub>S</sub> = 50 Ω			4			4			4		V	
gg-		Full range										-	
		i uli range	3.5			3.5			3.5				
		25°C	4	4.3		4	4.3		4	4.3			
High-level output voltage	D 4010	Full range	3.9			3.9			3.9			V	
Law law al autout walkana	H <sup>L</sup> = 10 KΩ	25°C		0.7	8.0		0.7	0.8		0.7	8.0	V	
Low-level output voltage		Full range			0.85			0.85			0.85	V	
Large-signal differential	V <sub>O</sub> = 1.4 V to 4 V,	25°C	0.3	1.5		0.3	1.5		0.3	1.5		V/µV	
voltage amplification	$R_L = 10 \text{ k}\Omega$	Full range	0.3			0.3			0.3			ν/μν	
Common mode rejection ratio	V <sub>IC</sub> = V <sub>ICR</sub> min,	25°C	85	110		85	110		85	110		dB	
Common-mode rejection ratio	$R_S = 50 \Omega$	Full range	80			80			80			uБ	
Supply-voltage rejection ratio	V F.V.+o.20.V	25°C	105	120		105	120		105	120		dB	
$(\Delta V_{CC}/\Delta V_{IO})$	V <sub>CC</sub> = 5 V to 30 V	Full range	100			100			100			uБ	
Supply current		25°C		200	300		200	300		200	300	μA	
	$V_0 = 2.5 \text{ V}$ . No load	Vo = 2.5 V. No load Full ranç	Vo = 2.5 V. No load Full range			300			300			300	μΛ
Supply-current change over operating temperature range	J === :, ::= :	Full range		5			5			5		μΑ	
	Input offset voltage long-term drift (see Note 4)  Input offset current  Input bias current  Common-mode input voltage range  High-level output voltage  Low-level output voltage  Large-signal differential voltage amplification  Common-mode rejection ratio  Supply-voltage rejection ratio  (ΔV <sub>CC</sub> /ΔV <sub>IO</sub> )  Supply current  Supply-current change over		$ \begin{array}{c} \text{Input offset voltage} \\ \text{Temperature coefficient of input offset voltage} \\ \text{Input offset voltage long-term drift (see Note 4)} \\ \text{Input offset voltage long-term drift (see Note 4)} \\ \text{Input offset current} \\ \text{Input offset current} \\ \\ \text{Input offset current} \\ \\ \text{Input bias current} \\ \\ \text{Common-mode input voltage range} \\ \text{R}_{S} = 50 \ \Omega \\ \\ \text{Full range} \\ \\ \text{Z5°C} \\ \\ \text{Full range} \\ \\ \text{Supply-voltage rejection ratio} \\ \text{Z5°C} \\ \\ \text{Full range} \\ \\ \text{Supply-voltage rejection ratio} \\ \text{Z5°C} \\ \\ \text{Full range} \\ \\ \text{Supply-current} \\ \\ \text{Supply-current change over operating temperature range} \\ \\ \text{Full range} \\ \\ Full$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	PARAMETER         TEST CONDITIONS         TA hold in the parameter of the product of the pr	PARAMETER         TEST CONDITIONS $T_A^+$ MIN         TYP         MAX           Input offset voltage         1 (25°C         1 (20)         6 (60)           Temperature coefficient of input offset voltage long-term drift (see Note 4)         25°C         0.0         25°C         0.0         25°C         0.0         25°C         0.0         25°C         0.0         0.0         25°C         0 <td rows<="" td=""><td>  PARAMETER   TEST CONDITIONS   TA   MIN   TYP   MAX   MIN    </td><td>  PARAMETER   TEST CONDITIONS   Table   Typ   MAX   MIN   Typ   MIN   MIN   MIN   Typ   MIN   MIN   Typ   MIN   MIN   Typ   MIN   Typ   MIN   MIN   Typ   MIN   Typ   MIN   Typ   MIN   MIN   Typ   T</td><td>  PARAMETER   TEST CONDITIONS   TA   MIN   TYP   MAX   MIN   MIN   TYP   MAX   MIN   MIN</td><td>  PARAMETER   TEST CONDITIONS   TA   MIN   TYP   MAX   MIN   MIN</td><td>  PARAMETER   TEST CONDITIONS   Tat   MIN   TYP   MAX   TYP   TYP</td><td>  PARAMETER   TEST CONDITIONS   Table   Table</td></td>	<td>  PARAMETER   TEST CONDITIONS   TA   MIN   TYP   MAX   MIN    </td> <td>  PARAMETER   TEST CONDITIONS   Table   Typ   MAX   MIN   Typ   MIN   MIN   MIN   Typ   MIN   MIN   Typ   MIN   MIN   Typ   MIN   Typ   MIN   MIN   Typ   MIN   Typ   MIN   Typ   MIN   MIN   Typ   T</td> <td>  PARAMETER   TEST CONDITIONS   TA   MIN   TYP   MAX   MIN   MIN   TYP   MAX   MIN   MIN</td> <td>  PARAMETER   TEST CONDITIONS   TA   MIN   TYP   MAX   MIN   MIN</td> <td>  PARAMETER   TEST CONDITIONS   Tat   MIN   TYP   MAX   TYP   TYP</td> <td>  PARAMETER   TEST CONDITIONS   Table   Table</td>	PARAMETER   TEST CONDITIONS   TA   MIN   TYP   MAX   MIN	PARAMETER   TEST CONDITIONS   Table   Typ   MAX   MIN   Typ   MIN   MIN   MIN   Typ   MIN   MIN   Typ   MIN   MIN   Typ   MIN   Typ   MIN   MIN   Typ   MIN   Typ   MIN   Typ   MIN   MIN   Typ   T	PARAMETER   TEST CONDITIONS   TA   MIN   TYP   MAX   MIN   MIN   TYP   MAX   MIN   MIN	PARAMETER   TEST CONDITIONS   TA   MIN   TYP   MAX   MIN   MIN	PARAMETER   TEST CONDITIONS   Tat   MIN   TYP   MAX   TYP   TYP	PARAMETER   TEST CONDITIONS   Table   Table

<sup>†</sup> Full range is 0°C to 70°C.

## TLE2021 electrical characteristics at specified free-air temperature, $V_{CC} = \pm 15 \text{ V}$ (unless otherwise noted)

		<u> </u>	•										
	DADAMETED	TEGT CONDITIONS	- +	Т	LE20210	;	TL	E2021AC	;	TL	E2021B0	;	
	PARAMETER	TEST CONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
.,			25°C		120	500		80	200		40	100	.,
$V_{IO}$	Input offset voltage		Full range			750			500			200	μV
$\alpha_{\text{VIO}}$	Temperature coefficient of input offset voltage	]	Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0$ , $R_S = 50 \Omega$	25°C		0.006			0.006			0.006		μV/mo
Ī	Lee Leffe at a surrent	]	25°C		0.2	6		0.2	6		0.2	6	0
I <sub>IO</sub>	Input offset current		Full range			10			10			10	nA
	Les these arms at		25°C		25	70		25	70		25	70	1
I <sub>IB</sub>	Input bias current		Full range			90			90			90	nA
			25°C	-15 to 13.5	-15.3 to 14		-15 to 13.5	-15.3 to 14		-15 to 13.5	-15.3 to 14		.,
V <sub>ICR</sub>	Common-mode input voltage range	$R_S = 50 \Omega$	Full range	-15 to 13.5			-15 to 13.5			-15 to 13.5			V
$V_{OM+}$	Maximum positive peak		25°C	14	14.3		14	14.3		14	14.3		V
VOM+	output voltage swing	R <sub>L</sub> = 10 kΩ	Full range	13.9			13.9			13.9			· ·
V <sub>OM -</sub>	Maximum negative peak		25°C	-13.7	-14.1		-13.7	-14.1		-13.7	-14.1		V
VOM –	output voltage swing		Full range	-13.7			-13.7			-13.7			
$A_{VD}$	Large-signal differential	$V_{O} = \pm 10 \text{ V},$	25°C	1	6.5		1	6.5		1	6.5		V/µV
<b>~</b> VD	voltage amplification	$R_L = 10 \text{ k}\Omega$	Full range	1			1			1			ν/μν
CMRR	Common-mode rejection ratio	V <sub>IC</sub> = V <sub>ICR</sub> min,	25°C	100	115		100	115		100	115		dB
OWN 117	Common-mode rejection ratio	$R_S = 50 \Omega$	Full range	96			96			96			uБ
k <sub>SVR</sub>	Supply-voltage rejection ratio	$V_{CC \pm} = \pm 2.5 \text{ V}$	25°C	105	120		105	120		105	120		dB
"SVH	$(\Delta V_{CC}/\Delta V_{IO})$	to ± 15 V	Full range	100			100			100			uD
I <sub>CC</sub>	Supply current		25°C		240	350		240	350		240	350	μА
-00		V <sub>O</sub> = 0, No load	Full range			350			350			350	,
$\Delta I_{CC}$	Supply-current change over operating temperature range		Full range		6			6			6		μΑ

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<sup>†</sup> Full range is 0°C to 70°C.

# TLE2022 electrical characteristics at specified free-air temperature, $V_{CC}$ = 5 V (unless otherwise noted)

	PARAMETER	TEST COND	ITIONS	<b>-</b> +	TL	_E20220	;	TL	E2022A	С	TL	E2022B	С	UNIT
	PANAMETEN	TEST COND	ITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
V	Input offset voltage			25°C			600			400			250	μV
$V_{IO}$	input offset voltage			Full range			800			550			400	μν
αVIO	Temperature coefficient of input offset voltage			Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	$R_S = 50 \Omega$	25°C		0.005			0.005			0.005		μV/mo
	Les Lefferde med	1		25°C		0.5	6		0.4	6		0.3	6	- 4
I <sub>IO</sub>	Input offset current			Full range			10			10			10	nA
	Lea Dice e and			25°C		35	70		33	70		30	70	- 4
I <sub>IB</sub>	Input bias current			Full range			90			90			90	nA
	Common-mode input	<b>D</b> 500		25°C	0 to 3.5	-0.3 to 4		0 to 3.5	-0.3 to 4		0 to 3.5	-0.3 to 4		.,
V <sub>ICR</sub>	voltage range	$R_S = 50 \Omega$		Full range	0 to 3.5			0 to 3.5			0 to 3.5			V
,,				25°C	4	4.3		4	4.3		4	4.3		.,
$V_{OH}$	High-level output voltage	D 4010		Full range	3.9			3.9			3.9			V
.,		$R_L = 10 \text{ k}\Omega$		25°C		0.7	8.0		0.7	8.0		0.7	8.0	.,
$V_{OL}$	Low-level output voltage			Full range			0.85			0.85			0.85	V
	Large-signal differential	V 4 4 V I - 4 V	D 4010	25°C	0.3	1.5		0.4	1.5		0.5	1.5		\// \/
A <sub>VD</sub>	voltage amplification	$V_O = 1.4 \text{ V to 4 V},$	$H_L = 10 \text{ K}\Omega$	Full range	0.3			0.4			0.5			V/μV
CMRR	Common made rejection ratio	\/ \/ min	D 500	25°C	85	100		87	102		90	105		dB
CIVIAA	Common-mode rejection ratio	$V_{IC} = V_{ICR}min,$	$R_S = 50 \Omega$	Full range	80			82			85			иь
1.	Supply-voltage rejection ratio	V 5 V to 20 V		25°C	100	115		103	118		105	120		dB
k <sub>SVR</sub>	$(\Delta V_{CC \pm}/\Delta V_{IO})$	$V_{CC}$ = 5 V to 30 V		Full range	95			98			100			ub
	Cumply ourrent			25°C		450	600		450	600		450	600	
I <sub>CC</sub>	Supply current	V <sub>O</sub> = 2.5 V,	No load	Full range			600			600			600	μА
$\Delta I_{CC}$	Supply current change over operating temperature range	- 2.0 •,	110 1000	Full range		7			7			7		μΑ

<sup>†</sup> Full range is 0°C to 70°C.

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at T<sub>A</sub> = 150°C extrapolated to T<sub>A</sub> = 25°C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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## TLE2022 electrical characteristics at specified free-air temperature, $V_{CC} = \pm 15 \text{ V}$ (unless otherwise noted)

	DADAMETED	TEST CON	DITIONS	_ +	Т	LE20220	;	TL	E2022A	С	TL	E2022B	С	UNIT
	PARAMETER	TEST CON	DITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNII
				25°C		150	500		120	300		70	150	
$V_{IO}$	Input offset voltage			Full range			700			450			300	μV
ανιο	Temperature coefficient of input offset voltage			Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	$R_S = 50 \Omega$	25°C		0.006			0.006			0.006		μV/mo
	Input offset current			25°C		0.5	6		0.4	6		0.3	6	nA
I <sub>IO</sub>	input onset current			Full range			10			10			10	ΠA
	Input bias current			25°C		35	70		33	70		30	70	nA
I <sub>IB</sub>	input bias current			Full range			90			90			90	ΠA
	Common-mode input	B 500		25°C	-15 to 13.5	-15.3 to 14		-15 to 13.5	-15.3 to 14		-15 to 13.5	-15.3 to 14		V
V <sub>ICR</sub>	voltage range	$R_S = 50 \Omega$		Full range	-15 to 13.5			-15 to 13.5			-15 to 13.5			V
V <sub>OM +</sub>	Maximum positive peak output voltage swing			25°C Full range	14 13.9	14.3		14 13.9	14.3		14 13.9	14.3		٧
	Maximum negative peak	$R_L = 10 \text{ k}\Omega$		25°C	-13.7	-14.1		-13.7	-14.1		-13.7	-14.1		
$V_{OM-}$	output voltage swing			Full range	-13.7			-13.7			-13.7			V
	Large-signal differential			25°C	0.8	4		1	7		1.5	10		
$A_{VD}$	voltage amplification	$V_0 = \pm 10 \text{ V},$	$R_L = 10 \text{ k}\Omega$	Full range	0.8			1			1.5			V/µV
OMBB	0	V V	D 500	25°C	95	106		97	109		100	112		-in
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}min,$	$R_S = 50 \Omega$	Full range	91			93			96			dB
1.	Supply-voltage rejection ratio	V 105V4	1451/	25°C	100	115		103	118		105	120		dB
k <sub>SVR</sub>	$(\Delta V_{CC\pm}/\Delta V_{IO})$	$V_{CC\pm} = \pm 2.5 \text{ V to}$	) ± 15 V	Full range	95			98			100			aB
laa	Supply ourrent			25°C		550	700		550	700		550	700	
I <sub>CC</sub>	Supply current	V <sub>O</sub> = 0,	No load	Full range			700			700			700	μΑ
$\Delta I_{CC}$	Supply current change over operating temperature range	-0 -5,	. 75 .554	Full range		9			9			9		μΑ

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<sup>†</sup> Full range is 0°C to 70°C.

## TLE2024 electrical characteristics at specified free-air temperature, V<sub>CC</sub> = 5 V (unless otherwise noted)

	DADAMETED	TEOT COND	TIONO	- +	TL	E20240	;	TL	E2024A	С	TL	E2024B	С	
	PARAMETER	TEST COND	IIIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
V <sub>IO</sub>	Input offset voltage			25°C			1100			850			600	μV
VΙΟ				Full range			1300			1050			800	μν
αVIO	Temperature coefficient of input offset voltage			Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	$R_S = 50 \Omega$	25°C		0.005			0.005			0.005		μV/mo
				25°C		0.6	6		0.5	6		0.4	6	
I <sub>IO</sub>	Input offset current			Full range			10			10			10	nA
	land bing a surrent			25°C		45	70		40	70		35	70	- 0
I <sub>IB</sub>	Input bias current			Full range			90			90			90	nA
	Common-mode input voltage			25°C	0 to 3.5	-0.3 to 4		0 to 3.5	-0.3 to 4		0 to 3.5	-0.3 to 4		.,
V <sub>ICR</sub>	range	$R_S = 50 \Omega$		Full range	0 to 3.5			0 to 3.5			0 to 3.5			V
V	High lavel as took values			25°C	3.9	4.2		3.9	4.2		4	4.3		V
V <sub>OH</sub>	High-level output voltage	D 40160		Full range	3.7			3.7			3.8			V
	Low-level output voltage	$R_L = 10 \text{ k}\Omega$		25°C		0.7	0.8		0.7	8.0		0.7	0.8	V
V <sub>OL</sub>	Low-level output voltage			Full range			0.95			0.95			0.95	V
۸	Large-signal differential	V <sub>O</sub> = 1.4 V to 4 V,	$R_L = 10 \text{ k}\Omega$	25°C	0.2	1.5		0.3	1.5		0.4	1.5		V/µV
A <sub>VD</sub>	voltage amplification	VO = 1.4 V to 4 V,	HL = 10 K22	Full range	0.1			0.1			0.1			ν/μν
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}min,$	$R_S = 50 \Omega$	25°C	80	90		82	92		85	95		dB
OWNTH	Common-mode rejection ratio	VIC - VICRIIIII,	118 - 30 22	Full range	80			82			85			ub.
<sup>k</sup> SVR	Supply-voltage rejection ratio	V <sub>CC</sub> = 5 V to 30 V		25°C	98	112		100	115		103	117		dB
	$(\Delta V_{CC}/\Delta V_{IO})$	-00 2 7 13 33 7		Full range	93			95			98			
I <sub>CC</sub>	Supply current			25°C		800	1200		800	1200		800	1200	μА
-00		V <sub>O</sub> = 2.5 V,	No load	Full range			1200			1200			1200	, ma
$\Delta$ I <sub>CC</sub>	Supply current change over operating temperature range			Full range		15			15			15		μΑ

<sup>†</sup> Full range is 0°C to 70°C.

## TLE2024 electrical characteristics at specified free-air temperature, $V_{CC}$ = $\pm 15$ V (unless otherwise noted)

					Т	LE20240		TL	E2024A	С	TL	E2024B	O	
	PARAMETER	TEST CONI	DITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
.,				25°C			1000			750			500	
$V_{IO}$	Input offset voltage			Full range			1200			950			700	μV
$\alpha$ VIO	Temperature coefficient of input offset voltage			Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	$R_S = 50 \Omega$	25°C		0.006			0.006			0.006		μV/mo
	Input offset current			25°C		0.6	6		0.5	6		0.4	6	nA
I <sub>IO</sub>	input offset current			Full range			10			10			10	ПA
	logest bigg growent			25°C		50	70		45	70		40	70	nA
I <sub>IB</sub>	Input bias current			Full range			90			90			90	IIA
	Common-mode input voltage			25°C	–15 to 13.5	–15.3 to 14		-15 to 13.5	–15.3 to 14		–15 to 13.5	-15.3 to 14		
V <sub>ICR</sub>	range	$R_S = 50 \Omega$		Full range	-15 to 13.5			-15 to 13.5			-15 to 13.5			V
V <sub>OM+</sub>	Maximum positive peak output voltage swing			25°C Full range	13.8 13.7	14.1		13.9 13.8	14.2		14 13.9	14.3		٧
	Maximum negative peak output	$R_L = 10 \text{ k}\Omega$		25°C	-13.7	-14.1		-13.7	-14.1		-13.7	-14.1		
$V_{OM-}$	voltage swing			Full range	-13.6			-13.6			-13.6			V
	Large-signal differential	V 140V	D 4010	25°C	0.4	2		0.8	4		1	7		\//\\
$A_{VD}$	voltage amplification	$V_0 = \pm 10 \text{ V},$	$R_L = 10 \text{ k}\Omega$	Full range	0.4			8.0			1			V/µV
CMRR	On many manda mainating matic	\ \ \\	D 500	25°C	92	102		94	105		97	108		dB
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}min,$	$R_S = 50 \Omega$	Full range	88			90			93			ав
k	Supply-voltage rejection ratio	$V_{CC\pm} = \pm 2.5 \text{ V to}$	±15 \/	25°C	98	112		100	115		103	117		dB
k <sub>SVR</sub>	$(\Delta V_{CC\pm}/\Delta V_{IO})$	VCC± - ± 2.3 V to	, <u> </u>	Full range	93			95			98			uБ
I <sub>CC</sub>	Supply current			25°C		1050	1400		1050	1400		1050	1400	μΑ
.00		V <sub>O</sub> = 0,	No load	Full range			1400			1400			1400	μιν
$\Delta I_{CC}$	Supply current change over operating temperature range			Full range		20			20			20		μΑ

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<sup>†</sup> Full range is 0°C to 70°C.

# TLE2021 electrical characteristics at specified free-air temperature, $V_{CC} = 5 \text{ V}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	T +	Т	LE2021		TL	E2021A	ı	TL	E2021B	SI .	UNIT
	PARAMETER	TEST CONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNII
V <sub>IO</sub>	Input offset voltage		25°C		120	600		100	300		80	200	μV
VIO			Full range			950			600			300	μ ν
$\alpha_{\text{VIO}}$	Temperature coefficient of input offset voltage		Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0$ , $R_S = 50 \Omega$	25°C		0.005			0.005			0.005		μV/mo
	land effect coment		25°C		0.2	6		0.2	6		0.2	6	^
I <sub>IO</sub>	Input offset current		Full range			10			10			10	nA
1	Input bias current		25°C		25	70		25	70		25	70	nA
I <sub>IB</sub>	input bias current		Full range			90			90			90	ΠA
				0	-0.3		0	-0.3		0	- 0.3		
			25°C	to 3.5	to 4		to 3.5	to 4		to 3.5	to 4		
$V_{\text{ICR}}$	Common-mode input voltage range	$R_S = 50 \Omega$		0.5	- 4		0.0	- 4					V
			Full range	to			to			0 to			
				3.2			3.2			3.2			
.,			25°C	4	4.3		4	4.3		4	4.3		.,
V <sub>OH</sub>	High-level output voltage	D 4010	Full range	3.9			3.9			3.9			V
.,		$R_L = 10 \text{ k}\Omega$	25°C		0.7	8.0		0.7	8.0		0.7	8.0	V
V <sub>OL</sub>	Low-level output voltage		Full range			0.9			0.9			0.9	V
_	Large-signal differential	V <sub>O</sub> = 1.4 V to 4 V,	25°C	0.3	1.5		0.3	1.5		0.3	1.5		\// <sub>*</sub> \/
$A_{VD}$	voltage amplification	$R_L = 10 \text{ k}\Omega$	Full range	0.25			0.25			0.25			V/μV
CMDD	Common mode rejection ratio	V <sub>IC</sub> = V <sub>ICR</sub> min,	25°C	85	110		85	110		85	110		dB
CMRR	Common-mode rejection ratio	$R_S = 50 \Omega$	Full range	80			80			80			uБ
le	Supply-voltage rejection ratio	\/	25°C	105	120		105	120		105	120		dB
k <sub>SVR</sub>	$(\Delta V_{CC}/\Delta V_{IO})$	$V_{CC} = 5 \text{ V to } 30 \text{ V}$	Full range	100			100			100			aв
	Cupalitation		25°C		200	300		200	300		200	300	4
I <sub>CC</sub>	Supply current	$V_0 = 2.5 V$ ,	Full range			300			300			300	μА
$\Delta I_{CC}$	Supply-current change over operating temperature range	No load	Full range		6			6			6		μΑ

<sup>†</sup> Full range is – 40°C to 85°C.

## TLE2021 electrical characteristics at specified free-air temperature, $V_{CC} = \pm 15 \text{ V}$ (unless otherwise noted)

	242445752	TEGT COMPLETIONS		Т	LE2021I		TI	E2021A	.I	TL	E2021B	SI .	
	PARAMETER	TEST CONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
.,			25°C		120	500		80	200		40	100	
$V_{IO}$	Input offset voltage		Full range			850			500			200	μV
$\alpha_{VIO}$	Temperature coefficient of input offset voltage		Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0$ , $R_S = 50 \Omega$	25°C		0.006			0.006			0.006		μV/mo
	land offers any and		25°C		0.2	6		0.2	6		0.2	6	^
I <sub>IO</sub>	Input offset current		Full range			10			10			10	nA
	Input bigg current		25°C		25	70		25	70		25	70	nA
I <sub>IB</sub>	Input bias current		Full range			90			90			90	ΠA
			25°C	–15 to	–15.3 to		–15 to	-15.3 to		–15 to	-15.3 to		
	Common-mode input voltage range	B 50.0		13.5	14		13.5	14		13.5	14		V
$V_{ICR}$		$R_S = 50 \Omega$		-15			-15			-15			V
			Full range	to 13.2			to 13.2			to 13.2			
.,	Maximum positive peak output		25°C	14	14.3		14	14.3		14	14.3		V
V <sub>OM +</sub>	voltage swing	D 4010	Full range	13.9			13.9			13.9			V
.,	Maximum negative peak output	$R_L = 10 \text{ k}\Omega$	25°C	-13.7	-14.1		-13.7	-14.1		-13.7	-14.1		V
V <sub>OM</sub> -	voltage swing		Full range	-13.6			-13.6			-13.6			V
_	Large-signal differential	V <sub>O</sub> = 10 V,	25°C	1	6.5		1	6.5		1	6.5		\// <sub>1</sub> .\/
A <sub>VD</sub>	voltage amplification	$R_L = 10 \text{ k}\Omega$	Full range	0.75			0.75			0.75			V/µV
CMRR	Common mode valention vetic	V <sub>IC</sub> = V <sub>ICR</sub> min,	25°C	100	115		100	115		100	115		dB
CIVIRR	Common-mode rejection ratio	$R_S = 50 \Omega$	Full range	96			96			96			αБ
le.	Supply-voltage rejection ratio	$V_{CC \pm} = \pm 2.5 \text{ V}$	25°C	105	120		105	120		105	120		dB
k <sub>SVR</sub>	$(\Delta V_{CC}/\Delta V_{IO})$	to ± 15 V	Full range	100			100			100			UD
laa	Supply current		25°C		240	350		240	350		240	350	^
I <sub>CC</sub>	оирріу сипепі	$V_O = 0 V$ , No load	Full range			350			350			350	μΑ
Δl <sub>CC</sub>	Supply-current change over operating temperature range	70 2 0 V, 140 ISAU	Full range		7			7			7		μΑ
	· · · · · · · · · · · · · · · · · · ·												

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<sup>&</sup>lt;sup>†</sup> Full range is – 40°C to 85°C.

# TLE2022 electrical characteristics at specified free-air temperature, $V_{CC}$ = 5 V (unless otherwise noted)

DADAMETED	TEST COND	ITIONS	<b>-</b> +	Т	LE2022		TL	.E2022A	.I	TL	E2022B	ı	UNIT
PANAMETEN	TEST COND	IIIONS	IA'	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Input offset voltage			25°C			600			400			250	μV
iliput oliset voltage			Full range			800			550			400	μν
Temperature coefficient of input offset voltage			Full range		2			2			2		μV/°C
Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	$R_S = 50 \Omega$	25°C		0.005			0.005			0.005		μV/mo
landa Marilan and			25°C		0.5	6		0.4	6		0.3	6	- 4
Input offset current			Full range			10			10			10	nA
			25°C		35	70		33	70		30	70	
Input bias current			Full range			90			90			90	nA
Common-mode input	<b>D </b> 00		25°C	0 to 3.5	-0.3 to 4		0 to 3.5	-0.3 to 4		0 to 3.5	-0.3 to 4		.,
voltage range	H <sub>S</sub> = 50 Ω		Full range	0 to 3.2			0 to 3.2			0 to 3.2			V
IPolo la calca la la clica a			25°C	4	4.3		4	4.3		4	4.3		.,
High-level output voltage	D 4010		Full range	3.9			3.9			3.9			V
La la da la la la la	$H_L = 10 \text{ K}\Omega$		25°C		0.7	8.0		0.7	8.0		0.7	8.0	.,
Low-level output voltage			Full range			0.9			0.9			0.9	V
Large-signal differential	\/	D 401-0	25°C	0.3	1.5		0.4	1.5		0.5	1.5		Man
voltage amplification	$V_0 = 1.4 \text{ V to 4 V},$	HL = 10 K22	Full range	0.2			0.2			0.2			V/μV
Common mode valention vatio	\/ \/ min	D F0.0	25°C	85	100		87	102		90	105		dB
Common-mode rejection ratio	V <sub>IC</sub> = V <sub>ICRIIIII</sub> ,	MS = 50 12	Full range	80			82			85			uБ
Supply-voltage rejection ratio	\/		25°C	100	115		103	118		105	120		dB
$(\Delta V_{CC\pm}/\Delta V_{IO})$	ACC = 2 A 10 20 A		Full range	95			98			100			uБ
Supply current			25°C		450	600		450	600		450	600	μΑ
очрріў синені	V <sub>O</sub> = 2.5 V.	No load	Full range			600			600			600	μΑ
Supply current change over operating temperature range			Full range		15			15	_		15		μΑ
	Input offset voltage Input offset voltage long-term drift (see Note 4) Input offset current Input bias current  Common-mode input voltage range  High-level output voltage  Low-level output voltage  Large-signal differential voltage amplification  Common-mode rejection ratio  Supply-voltage rejection ratio  (\( \Delta V_{CC \pm } / \Delta V_{IO} \)  Supply current  Supply current change over				$ \begin{array}{ c c c c c } \hline PARAMETER & TEST CONDITIONS & T_A^{\dagger} & \hline MINI \\ \hline Input offset voltage \\ \hline Temperature coefficient of input offset voltage \\ Input offset voltage long-term drift (see Note 4) \\ \hline Input offset current \\ \hline Input offset current \\ \hline Input bias current \\ \hline Common-mode input voltage \\ \hline High-level output voltage \\ \hline Large-signal differential voltage amplification & V_{IC} = V_{ICR}min, & R_S = 50 \Omega & 5^{\circ}C $	PARAMETER   TEST CONDITIONS   TA	Input offset voltage   Full range   Full	PARAMETER         TEST CONDITIONS         T <sub>A</sub> <sup>†</sup> MIN         TYP         MAX         MIN           Input offset voltage         Pull range         5°C         0.005         800         1           Imput offset voltage long-term drift (see Note 4)         VIC = 0.         R <sub>S</sub> = 50 Ω         25°C         0.005         6         1           Imput offset voltage long-term drift (see Note 4)         VIC = 0.         R <sub>S</sub> = 50 Ω         25°C         0.55         6         1           Imput offset voltage long-term drift (see Note 4)         Full range         0.05         6         1           Imput offset voltage long-term drift (see Note 4)         Full range         0.05         6         1           Imput offset voltage long-term drift (see Note 4)         Full range         0.05         6         1           Imput offset voltage long-term drift (see Note 4)         Full range         0.05         0	PARAMETER   TEST CONDITIONS   TAT   MIN   TYP   MAX   MIN   TYP   MIN   TYP   MIN   TYP   MIN   TYP   MIN   MI	PARAMETER   TEST CONDITIONS   TA'   MIN   TYP   MAX   MIN   MIN	PARAMETER   TEST CONDITIONS   TAT   MIN   TYP   MAX   MIN   TYP   TY	PARAMETER   TEST CONDITIONS   TATE   TATE	PARAMETER   TEST CONDITIONS   TAT   TA

<sup>&</sup>lt;sup>†</sup> Full range is – 40°C to 85°C.

## TLE2022 electrical characteristics at specified free-air temperature, $V_{CC} = \pm 15 \text{ V}$ (unless otherwise noted)

		•		•				•				•		
	24244555		DITIONS		1	LE2022I		Т	LE2022A	J	Т	LE2022B	I	
	PARAMETER	TEST CON	DITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
				25°C		150	500		120	300		70	150	
$V_{IO}$	Input offset voltage			Full range			700			450			300	μV
ανιο	Temperature coefficient of input offset voltage			Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	R <sub>S</sub> = 50 Ω	25°C		0.006			0.006			0.006		μV/mo
	lanut offeet europa			25°C		0.5	6		0.4	6		0.3	6	nA
I <sub>IO</sub>	Input offset current			Full range			10			10			10	ΠA
	Input bias current			25°C		35	70		33	70		30	70	nA
I <sub>IB</sub>	input bias current			Full range			90			90			90	IIA
	Common-mode input			25°C	- 15 to 13.5	-15.3 to 14		- 15 to 13.5	-15.3 to 14		- 15 to 13.5	-15.3 to 14		
V <sub>ICR</sub>	voltage range	$H_S = 50 \Omega$	= 50 Ω	Full range	- 15 to 13.2			- 15 to 13.2			– 15 to 13.2			V
V	Maximum positive peak			25°C	14	14.3		14	14.3		14	14.3		V
V <sub>OM +</sub>	output voltage swing	D 401-0		Full range	13.9			13.9			13.9			V
.,	Maximum negative peak	$R_L = 10 \text{ k}\Omega$		25°C	- 13.7	- 14.1		- 13.7	- 14.1		- 13.7	- 14.1		V
V <sub>OM</sub> –	output voltage swing			Full range	- 13.6			- 13.6			- 13.6			V
	Large-signal differential	V 140V	D 4010	25°C	0.8	4		1	7		1.5	10		\(\(\)\(\)
$A_{VD}$	voltage amplification	$V_0 = \pm 10 \text{ V},$	$R_L = 10 \text{ k}\Omega$	Full range	0.8			1			1.5			V/µV
CMRR	Common made rejection ratio	\ \ \ min	D 500	25°C	95	106		97	109		100	112		dB
CWIRK	Common-mode rejection ratio	$V_{IC} = V_{ICR}min,$	$R_S = 50 \Omega$	Full range	91			93			96			иБ
	Supply-voltage rejection ratio	V 105V45	1.4E.V/	25°C	100	115		103	118		105	120		dB
k <sub>SVR</sub>	$(\Delta V_{CC\pm}/\Delta V_{IO})$	$V_{CC} = \pm 2.5 \text{ V to}$	± 13 V	Full range	95			98			100			uБ
1	Cupply ourront			25°C		550	700		550	700		550	700	
I <sub>CC</sub>	Supply current	V <sub>O</sub> = 0,	No load	Full range			700			700			700	μΑ
Δl <sub>CC</sub>	Supply current change over operating temperature range	VO = 0,		Full range		30			30			30		μА
	-													

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<sup>&</sup>lt;sup>†</sup> Full range is –40°C to 85°C.

## TLE2024 electrical characteristics at specified free-air temperature, $V_{CC} = 5 \text{ V}$ (unless otherwise noted)

	DADAMETED	TEST COND	ITIONS	- +	T	LE2024I		TL	E2024A	I	TL	E2024B	I	UNIT
	PARAMETER	TEST COND	IIIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNII
V <sub>IO</sub>	Input offset voltage			25°C			1100			850			600	μV
VIO	iliput oliset voltage			Full range			1300			1050			800	μν
αVIO	Temperature coefficient of input offset voltage			Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	R <sub>S</sub> = 50 Ω	25°C		0.005			0.005			0.005		μV/mo
		1		25°C		0.6	6		0.5	6		0.4	6	
I <sub>IO</sub>	Input offset current			Full range			10			10			10	nA
	land this summer			25°C		45	70		40	70		35	70	nA
I <sub>IB</sub>	Input bias current			Full range			90			90			90	nA
,	Common-mode input voltage	B 500		25°C	0 to 3.5	-0.3 to 4		0 to 3.5	-0.3 to 4		0 to 3.5	-0.3 to 4		,
V <sub>ICR</sub>	range	R <sub>S</sub> = 50 Ω		Full range	0 to 3.2			0 to 3.2			0 to 3.2			V
V	Maximum positive peak			25°C	3.9	4.2		3.9	4.2		4	4.3		V
V <sub>OM+</sub>	output voltage swing	D 1010		Full range	3.7			3.7			3.8			V
V	Maximum negative peak	$R_L = 10 \text{ k}\Omega$		25°C		0.7	8.0		0.7	0.8		0.7	0.8	V
$V_{OM-}$	output voltage swing			Full range			0.95			0.95			0.95	V
<b>\</b>	Large-signal differential	V <sub>O</sub> = 1.4 V to 4 V,	$R_L = 10 \text{ k}\Omega$	25°C	0.2	1.5		0.3	1.5		0.4	1.5		V/µV
A <sub>VD</sub>	voltage amplification	V <sub>O</sub> = 1.4 V to 4 V,	U[ = 10 K22	Full range	0.1			0.1			0.1			ν/μν
CMRR	Common-mode rejection ratio	V <sub>IC</sub> = V <sub>ICR</sub> min,	$R_S = 50 \Omega$	25°C	80	90		82	92		85	95		dB
OWNT	Common-mode rejection ratio	VIC - VICRITIIII,	11g = 30 sz	Full range	80			82			85			uБ
ksvr	Supply-voltage rejection ratio	$V_{CC\pm} = \pm 2.5 \text{ V to } \pm 1.0 \text{ V}$	15 V	25°C	98	112		100	115		103	117		dB
OVIT	$(\Delta V_{CC\pm}/\Delta V_{IO})$	V <sub>UU±</sub> - ±2.5 V t0 ±	10 v	Full range	93			95			98			uD.
I <sub>CC</sub>	Supply current			25°C		800	1200		800	1200		800	1200	μA
		$V_{O} = 0,$	No load	Full range			1200			1200			1200	μ, ,
$\Delta I_{CC}$	Supply current change over operating temperature range			Full range		30			30			30		μΑ

<sup>†</sup> Full range is – 40°C to 85°C.

## TLE2024 electrical characteristics at specified free-air temperature, $V_{CC} = \pm 15 \text{ V}$ (unless otherwise noted)

	DADAMETED	TEST CON	DITIONS	<b>-</b> +	Т	LE2024I	i	TI	E2024A	AI .	TL	LE2024B	,I	UNIT
	PARAMETER	TEST CONE	JIIIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNII
Ţ,	In a start affect voltage			25°C			1000			750			500	μV
$V_{IO}$	Input offset voltage			Full range			1200			950			700	μν
αVIO	Temperature coefficient of input offset voltage			Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	$R_S = 50 \Omega$	25°C		0.006			0.006			0.006		μV/mo
	land affect oursent			25°C		0.6	6		0.5	6		0.4	6	~^
I <sub>IO</sub>	Input offset current			Full range			10			10			10	nA
	L			25°C		50	70		45	70		40	70	1
I <sub>IB</sub>	Input bias current			Full range			90			90			90	nA
	Common-mode input voltage			25°C	-15 to 13.5	-15.3 to 14		-15 to 13.5	-15.3 to 14		–15 to 13.5	-15.3 to 14		
V <sub>ICR</sub>	range	$R_S = 50 \Omega$		Full range	-15 to 13.2			-15 to 13.2			-15 to 13.2			V
V <sub>OM+</sub>	Maximum positive peak output voltage swing			25°C Full range	13.8 13.7	14.1		13.9 13.7	14.2		14 13.8	14.3		٧
	Maximum negative peak output	$R_L = 10 \text{ k}\Omega$		25°C	-13.7	-14.1		-13.7	-14.1		-13.7	-14.1		
$V_{OM-}$	voltage swing			Full range	-13.6			-13.6	•		-13.6			٧
	Large-signal differential			25°C	0.4	2		0.8	4		1	7		
$A_{VD}$	voltage amplification	$V_0 = \pm 10 \text{ V},$	$R_L = 10 \text{ k}\Omega$	Full range	0.4			0.8			1			V/µV
		1		25°C	92	102		94	105		97	108		
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}min,$	$R_S = 50 \Omega$	Full range	88			90			93			dB
<u>.                                      </u>	Supply-voltage rejection ratio			25°C	98	112		100	115		103	117		
k <sub>SVR</sub>	$(\Delta V_{CC\pm}/\Delta V_{IO})$	$V_{CC\pm} = \pm 2.5 \text{ V to}$	±15 V	Full range	93			95			98			dB
	O col sumant			25°C		1050	1400		1050	1400		1050	1400	
Icc	Supply current	V <sub>O</sub> = 0,	No load	Full range			1400			1400			1400	μΑ
$\Delta$ I <sub>CC</sub>	Supply current change over operating temperature range	<b>v</b> 0 = 0,	No load	Full range		50			50			50		μА

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<sup>†</sup> Full range is – 40°C to 85°C.

## TLE2021 electrical characteristics at specified free-air temperature, $V_{CC} = 5 \text{ V}$ (unless otherwise noted)

	PARAMETER	TEST CONI	DITIONS	<b>-</b> +	TL	E2021N	١	TLI	E2021B	М	UNIT
	PANAMETEN	TEST CONL	DITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	UNII
V <sub>IO</sub>	Input offset voltage			25°C		120	600		80	200	μV
VIO.	input onset voitage			Full range			1100			300	μν
ανιο	Temperature coefficient of input offset voltage			Full range		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	$R_S = 50 \Omega$	25°C		0.005			0.005		μV/mo
1	Input offset current			25°C		0.2	6		0.2	6	nA
I <sub>IO</sub>	Input offset current			Full range			10			10	IIA
Ī	Input bigg gurrent			25°C		25	70		25	70	nA
I <sub>IB</sub>	Input bias current			Full range			90			90	IIA
					0	-0.3		0	-0.3		
	-			25°C	to 3.5	to 4		to 3.5	to 4		
V <sub>ICR</sub>	Common-mode input voltage range	$R_S = 50 \Omega$			0	4		0	4		٧
	voltage range			Full range	to			to			
				I all raings	3.2			3.2			
<u> </u>				25°C	4	4.3		4	4.3		,,
V <sub>OH</sub>	High-level output voltage			Full range	3.8			3.8			V
	I I I I I I I I I I I I I I I I I I I	$R_L = 10 \text{ k}\Omega$		25°C		0.7	8.0		0.7	0.8	
V <sub>OL</sub>	Low-level output voltage			Full range			0.95			0.95	٧
_	Large-signal differential	14 4 1/40 4 1/4	D 4010	25°C	0.3	1.5		0.3	1.5		MA
$A_{VD}$	voltage amplification	$V_O = 1.4 \text{ V to 4 V},$	H <sub>L</sub> = 10 KΩ	Full range	0.1			0.1			V/µV
OMPD	O de setedire selle		5 500	25°C	85	110		85	110		JD.
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}min,$	$R_S = 50 \Omega$	Full range	80			80			dB
l,	Supply-voltage rejection ratio	5)/1-00)/		25°C	105	120		105	120		JD.
k <sub>SVR</sub>	$(\Delta V_{CC\pm}/\Delta V_{IO})$	V <sub>CC</sub> = 5 V to 30 V		Full range	100			100			dB
	<b>2</b>			25°C		170	230		170	230	_
ICC	Supply current	V 25 V	No load	Full range			230			230	μΑ
Δl <sub>CC</sub>	Supply current change over operating temperature range	V <sub>0</sub> = 2.3 v,	NO IOau	Full range	_	9	_	_	9		μА
I <sub>CC</sub> ΔI <sub>CC</sub>	Supply current Supply current change over	- V <sub>O</sub> = 2.5 V,	No load	25°C Full range							

<sup>&</sup>lt;sup>†</sup> Full range is –55°C to 125°C.

## TLE2021 electrical characteristics at specified free-air temperature, $V_{CC} = \pm 15 \text{ V}$ (unless otherwise noted)

	212111777	7507.001	DITIONS		TI	_E2021N	1	TL	E2021B	М	
	PARAMETER	TEST CON	DITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
V	land offertualies			25°C		120	500		40	100	/
$V_{IO}$	Input offset voltage			Full range			1000			200	μV
ανιο	Temperature coefficient of input offset voltage			Full range		2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	$V_{IC} = 0$ ,	$R_S = 50 \Omega$	25°C		0.006			0.006		μV/mo
	Landa Marilan and	7		25°C		0.2	6		0.2	6	- 4
I <sub>IO</sub>	Input offset current			Full range			10			10	nA
	land him accord	7		25°C		25	70		25	70	0
I <sub>IB</sub>	Input bias current			Full range			90			90	nA
	Common-mode input	B 500		25°C	-15 to 13.5	-15.3 to 14		–15 to 13.5	-15.3 to 14		
V <sub>ICR</sub>	voltage range	$R_S = 50 \Omega$		Full range	-15 to 13.2			-15 to 13.2			V
V	Maximum positive peak			25°C	14	14.3		14	14.3		V
V <sub>OM+</sub>	output voltage swing	$R_1 = 10 \text{ k}\Omega$		Full range	13.8			13.8			V
V	Maximum negative peak	H[ = 10 K22		25°C	-13.7	-14.1		-13.7	-14.1		V
V <sub>OM</sub> –	output voltage swing			Full range	-13.6			-13.6			V
Δ	Large-signal differential	$V_{O} = \pm 10 \text{ V},$	$R_I = 10 \text{ k}\Omega$	25°C	1	6.5		1	6.5		V/µV
A <sub>VD</sub>	voltage amplification	V <sub>O</sub> = ±10 V,	11[ = 10 K22	Full range	0.5			0.5			<b>ν</b> /μ <b>ν</b>
CMRR	Common-mode rejection ratio	V <sub>IC</sub> = V <sub>ICR</sub> min,	$R_S = 50 \Omega$	25°C	100	115		100	115		dB
OWNT	Common-mode rejection ratio	AIC - AICHIIIII	11g = 30 sz	Full range	96			96			uБ
k <sub>SVR</sub>	Supply-voltage rejection ratio	$V_{CC^{+}} = \pm 2.5 \text{ V to}$	+15 V	25°C	105	120		105	120		dB
SVH	$(\Delta V_{CC\pm}/\Delta V_{IO})$	100± = <b>=</b> .0 1 to		Full range	100			100			
I <sub>CC</sub>	Supply current			25°C		200	300		200	300	μΑ
Δl <sub>CC</sub>	Supply current change over operating temperature range	$V_O = 0$ ,	No load	Full range Full range		10	300		10	300	μА

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<sup>†</sup> Full range is – 55°C to 125°C.

# TLE2022 electrical characteristics at specified free-air temperature, $V_{CC}$ = 5 V (unless otherwise noted)

	PARAMETER	TEST COND	ITIONS	<b>-</b> +	TL	E2022N	1	TL	E2022A	М	TL	E2022B	М	UNIT
	PANAMETEN	TEST COND	ITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNII
<b>.</b> ,	Input offset voltage			25°C			600			400			250	μV
$V_{IO}$	input onset voltage			Full range			800			550			400	μν
ανιο	Temperature coefficient of input offset voltage			Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	R <sub>S</sub> = 50 Ω	25°C		0.005			0.005			0.005		μ <b>V</b> /mo
		1		25°C		0.5	6		0.4	6		0.3	6	- 4
I <sub>IO</sub>	Input offset current			Full range			10			10			10	nA
	Lea Distance and	1		25°C		35	70		33	70		30	70	- 4
I <sub>IB</sub>	Input bias current			Full range			90			90			90	nA
.,	Common-mode input	B 500		25°C	0 to 3.5	-0.3 to 4		0 to 3.5	-0.3 to 4		0 to 3.5	-0.3 to 4		.,
V <sub>ICR</sub>	voltage range	$R_S = 50 \Omega$		Full range	0 to 3.2			0 to 3.2			0 to 3.2			V
, , , , , , , , , , , , , , , , , , ,	High lavel autout vallages			25°C	4	4.3		4	4.3		4	4.3		V
V <sub>OH</sub>	High-level output voltage	D 401-0		Full range	3.8			3.8			3.8			V
, , , , , , , , , , , , , , , , , , ,	I am laval autorit valta aa	$R_L = 10 \text{ k}\Omega$		25°C		0.7	0.8		0.7	0.8		0.7	0.8	V
$V_{OL}$	Low-level output voltage			Full range			0.95			0.95			0.95	V
	Large-signal differential	\/ 4 4\\\\	D 401-0	25°C	0.3	1.5		0.4	1.5		0.5	1.5		MA
$A_{VD}$	voltage amplification	$V_0 = 1.4 \text{ V to 4 V},$	$H_{\Gamma} = 10 \text{ k}75$	Full range	0.1			0.1			0.1			V/µV
CMRR	Common-mode rejection ratio	\/ \/ min	$R_S = 50 \Omega$	25°C	85	100		87	102		90	105		dB
CIVINA	Common-mode rejection ratio	$V_{IC} = V_{ICR}$ min,	ng = 30 12	Full range	80			82			85			uБ
ka	Supply-voltage rejection ratio	V <sub>CC</sub> = 5 V to 30 V		25°C	100	115		103	118		105	120		dB
k <sub>SVR</sub>	$(\Delta V_{CC\pm}/\Delta V_{IO})$	ACC = 2 A 10 30 A		Full range	95			98			100			uБ
I <sub>CC</sub>	Supply current			25°C		450	600		450	600		450	600	μА
icc	очрріў сипені	V <sub>O</sub> = 2.5 V,	No load	Full range			600			600			600	μΛ
$\Delta I_{CC}$	Supply current change over operating temperature range	· 0 - 2.0 v,	.10 1044	Full range		37			37			37		μΑ
† Full ran	ge is _55°C to 125°C													

Full range is – 55°C to 125°C

## TLE2022 electrical characteristics at specified free-air temperature, $V_{CC} = \pm 15 \text{ V}$ (unless otherwise noted)

		•		•	•			•				•		
	DADAMETED	TEGT COM	DITIONO	_ +	T	LE2022N	1	TL	E2022A	М	TL	E2022B	М	
	PARAMETER	TEST CON	DITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
.,				25°C		150	500		120	300		70	150	
$V_{IO}$	Input offset voltage			Full range			700			450			300	μV
αVIO	Temperature coefficient of input offset voltage			Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	$R_S = 50 \Omega$	25°C		0.006			0.006			0.006		μV/mo
	Inner afford occurrent			25°C		0.5	6		0.4	6		0.3	6	nA
I <sub>IO</sub>	Input offset current			Full range			10			10			10	nA
	land him a mant			25°C		35	70		33	70		30	70	^
I <sub>IB</sub>	Input bias current			Full range			90			90			90	nA
.,	Common-mode input	<b>D 50</b> 0		25°C	-15 to 13.5	-15.3 to 14		-15 to 13.5	-15.3 to 14		-15 to 13.5	-15.3 to 14		
V <sub>ICR</sub>	voltage range	$R_S = 50 \Omega$		Full range	-15 to 13.2			-15 to 13.2			-15 to 13.2			V
V <sub>OM +</sub>	Maximum positive peak output voltage swing			25°C Full range	14 13.9	14.3		14 13.9	14.3		14 13.9	14.3		٧
	Maximum negative peak	$R_L = 10 \text{ k}\Omega$		25°C	-13.7	-14.1		-13.7	-14.1		-13.7	-14.1		
$V_{OM-}$	output voltage swing			Full range	-13.6			-13.6			-13.6			V
	Large-signal differential			25°C	0.8	4		1	7		1.5	10		
$A_{VD}$	voltage amplification	$V_0 = \pm 10 \text{ V},$	$R_L = 10 \text{ k}\Omega$	Full range	0.8			1			1.5			V/µV
			_	25°C	95	106		97	109		100	112		
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}min,$	$R_S = 50 \Omega$	Full range	91			93			96			dB
	Supply-voltage rejection ratio			25°C	100	115		103	118		105	120		
k <sub>SVR</sub>	$(\Delta V_{CC\pm}/\Delta V_{IO})$	$V_{CC\pm} = \pm 2.5 \text{ V to}$	±15 V	Full range	95			98			100			dB
	0 1 1			25°C		550	700		550	700		550	700	
I <sub>CC</sub>	Supply current	V <sub>O</sub> = 0,	No load	Full range			700			700			700	μΑ
Δl <sub>CC</sub>	Supply current change over operating temperature range	ν <sub>O</sub> = υ,	INO IORU	Full range		60			60			60		μΑ

<sup>†</sup> Full range is –55°C to 125°C.

## TLE2024 electrical characteristics at specified free-air temperature, $V_{CC} = 5 \text{ V}$ (unless otherwise noted)

	DADAMETED	TEST COND	ITIONS	- +	TL	.E2024N	1	TL	E2024A	M	TLI	E2024BI	M	UNIT
	PARAMETER	TEST COND	IIIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNII
Via	Input offset voltage			25°C			1100			850			600	μV
$V_{IO}$	input oliset voltage			Full range			1300			1050			800	μν
αVIO	Temperature coefficient of input offset voltage			Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	R <sub>S</sub> = 50 Ω	25°C		0.005			0.005			0.005		μV/mo
		1		25°C		0.6	6		0.5	6		0.4	6	
I <sub>IO</sub>	Input offset current			Full range			10			10			10	nA
	land him a mant			25°C		45	70		40	70		35	70	- 0
I <sub>IB</sub>	Input bias current			Full range			90			90			90	nA
	Common-mode input voltage	<b>D 50</b> 0		25°C	0 to 3.5	-0.3 to 4		0 to 3.5	-0.3 to 4		0 to 3.5	-0.3 to 4		.,
V <sub>ICR</sub>	range	R <sub>S</sub> = 50 Ω		Full range	0 to 3.2			0 to 3.2			0 to 3.2			V
V	Maximum positive peak			25°C	3.9	4.2		3.9	4.2		4	4.3		V
V <sub>OM+</sub>	output voltage swing	D 1010		Full range	3.7			3.7			3.8			V
V	Maximum negative peak	$R_L = 10 \text{ k}\Omega$		25°C		0.7	8.0		0.7	8.0		0.7	0.8	V
V <sub>OM</sub> –	output voltage swing			Full range			0.95			0.95			0.95	V
<b>_</b>	Large-signal differential	V <sub>O</sub> = 1.4 V to 4 V,	$R_L = 10 \text{ k}\Omega$	25°C	0.2	1.5		0.3	1.5		0.4	1.5		V/µV
A <sub>VD</sub>	voltage amplification	V <sub>O</sub> = 1.4 V to 4 V,	U[ = 10 K22	Full range	0.1			0.1			0.1			ν/μν
CMRR	Common-mode rejection ratio	V <sub>IC</sub> = V <sub>ICR</sub> min,	$R_S = 50 \Omega$	25°C	80	90		82	92		85	95		dB
OWNT	Common-mode rejection ratio	VIC - VICRITIIII,	11g = 30 sz	Full range	80			82			85			uБ
ksvr	Supply-voltage rejection ratio	$V_{CC\pm} = \pm 2.5 \text{ V to } \pm 1.0 \text{ V}$	15 V	25°C	98	112		100	115		103	117		dB
OVII	$(\Delta V_{CC\pm}/\Delta V_{IO})$	V <sub>UU±</sub> - ±2.5 V t0 ±	10 v	Full range	93			95			98			uD.
I <sub>CC</sub>	Supply current			25°C		800	1200		800	1200		800	1200	μA
.00		V <sub>O</sub> = 0,	No load	Full range			1200			1200			1200	μι
$\Delta I_{CC}$	Supply current change over operating temperature range	,		Full range		50			50			50		μΑ

<sup>†</sup> Full range is – 55°C to 125°C.

## TLE2024 electrical characteristics at specified free-air temperature, $V_{CC} = \pm 15 \text{ V}$ (unless otherwise noted)

					TI	_E2024N	1	TL	E2024A	М	TL	E2024BI	М	
	PARAMETER	TEST CONI	DITIONS	T <sub>A</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
				25°C			1000			750			500	
$V_{IO}$	Input offset voltage			Full range			1200			950			700	μV
αVIO	Temperature coefficient of input offset voltage			Full range		2			2			2		μV/°C
	Input offset voltage long-term drift (see Note 4)	V <sub>IC</sub> = 0,	$R_S = 50 \Omega$	25°C		0.006			0.006			0.006		μV/mo
	long toffact aggreent	1		25°C		0.6	6		0.5	6		0.4	6	nA
I <sub>IO</sub>	Input offset current			Full range			10			10			10	ПA
1	Input bias current			25°C		50	70		45	70		40	70	nA
I <sub>IB</sub>	input bias current			Full range			90			90			90	ΠA
	Common-mode input voltage			25°C	–15 to 13.5	-15.3 to 14		–15 to 13.5	-15.3 to 14		–15 to 13.5	-15.3 to 14		
V <sub>ICR</sub>	range	$R_S = 50 \Omega$		Full range	-15 to 13.2			-15 to 13.2			-15 to 13.2			V
V <sub>OM+</sub>	Maximum positive peak output voltage swing			25°C Full range	13.8 13.7	14.1		13.9 13.7	14.2		14 13.8	14.3		V
	Maximum negative peak output	$R_L = 10 \text{ k}\Omega$		25°C	-13.7	-14.1		-13.7	-14.1		-13.7	-14.1		
$V_{OM-}$	voltage swing			Full range	-13.6			-13.6			-13.6			V
	Large-signal differential		<b>D</b> 4010	25°C	0.4	2		0.8	4		1	7		
$A_{VD}$	voltage amplification	$V_0 = \pm 10 \text{ V},$	$R_L = 10 \text{ k}\Omega$	Full range	0.4			0.8			1			V/µV
OMBB	0	V V	D 500	25°C	92	102		94	105		97	108		-ID
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}min$ ,	$R_S = 50 \Omega$	Full range	88			90			93			dB
le .	Supply-voltage rejection ratio	$V_{CC\pm} = \pm 2.5 \text{ V to}$	±15 \/	25°C	98	112		100	115		103	117		dB
k <sub>SVR</sub>	$(\Delta V_{CC\pm}/\Delta V_{IO})$	VCC± = ± 2.3 V to	, _ 10 V	Full range	93			95			98			uБ
loo	Supply current			25°C		1050	1400		1050	1400		1050	1400	μА
I <sub>CC</sub>	очрріў очітопі	V <sub>O</sub> = 0,	No load	Full range			1400			1400			1400	μΛ
$\Delta$ I <sub>CC</sub>	Supply current change over operating temperature range	-,		Full range		85			85			85		μА

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<sup>†</sup> Full range is – 55°C to 125°C.

## TLE2021 operating characteristics, $V_{CC}$ = 5 V, $T_A$ = 25°C

	DADAMETED	TEST SOMBITIONS	-	С	SUFFIX		18	SUFFIX		М	SUFFIX		
	PARAMETER	TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	V <sub>O</sub> = 1 V to 3 V, See Figure 1	25°C		0.5			0.5			0.5		V/μs
, , , , , , , , , , , , , , , , , , ,	Equivalent input noise voltage	f = 10 Hz	25°C		21	50		21	50		21		->/// !
V <sub>n</sub>	(see Figure 2)	f = 1 kHz	25°C		17	30		17	30		17		nV/Hz
,	Peak-to-peak equivalent input	f = 0.1 to 1 Hz	25°C		0.16			0.16			0.16		
V <sub>N(PP)</sub>	noise voltage	f = 0.1 to 10 Hz	25°C		0.47			0.47			0.47		μV
In	Equivalent input noise current		25°C		0.09			0.09			0.9		pA/Hz
B <sub>1</sub>	Unity-gain bandwidth	See Figure 3	25°C		1.2		·	1.2		•	1.2	Ī	MHz
φ <sub>m</sub>	Phase margin at unity gain	See Figure 3	25°C		42°			42°			42°		

## TLE2021 operating characteristics at specified free-air temperature, $V_{CC}$ = $\pm 15~V$

DADAMETED	TEST SON	IDITIONS		С	SUFFIX	(		SUFFIX	,	М	SUFFIX	<	
PARAMETER	TEST CONF	SHIONS	IA1	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Class rate at smits rain	\/ 4\/+= 0\/	Con Figure 4	25°C	0.45	0.65		0.45	0.65		0.45	0.65		Mar
Siew rate at unity gain	$V_0 = 10 \text{ to 3 V},$	See Figure 1	Full range	0.45			0.42			0.45			V/μs
Equivalent input noise voltage	f = 10 Hz		25°C		19	50		19	50	1	19		-> //! !-
(see Figure 2)	f = 1 kHz	•	25°C		15	30	ĺ	15	30	ĺ	15		nV/Hz
Peak-to-peak equivalent input	f = 0.1 to 1 Hz	•	25°C		0.16			0.16		1	0.16		
noise voltage	f = 0.1 to 10 Hz		25°C		0.47			0.47	7	[	0.47		μV
Equivalent input noise current		•	25°C		0.09		ĺ	0.09	7	ĺ	0.09		pA/Hz
Unity-gain bandwidth	See Figure 3	•	25°C		2			2		1	2		MHz
Phase margin at unity gain	See Figure 3	· · · · · · · · · · · · · · · · · · ·	25°C		46°			46°		1	46°	7	
	(see Figure 2)  Peak-to-peak equivalent input noise voltage  Equivalent input noise current  Unity-gain bandwidth	Slew rate at unity gain $V_O = 1V \text{ to } 3 \text{ V},$ Equivalent input noise voltage (see Figure 2)  Peak-to-peak equivalent input noise voltage $f = 10 \text{ Hz}$ $f = 1 \text{ kHz}$ $f = 0.1 \text{ to } 1 \text{ Hz}$ $f = 0.1 \text{ to } 10 \text{ Hz}$ Equivalent input noise current  Unity-gain bandwidth  See Figure 3	Slew rate at unity gain $V_0 = 1V \text{ to } 3 \text{ V}$ , See Figure 1  Equivalent input noise voltage (see Figure 2)  Peak-to-peak equivalent input noise voltage $f = 10 \text{ Hz}$ $f = 1 \text{ kHz}$ $f = 0.1 \text{ to } 1 \text{ Hz}$ $f = 0.1 \text{ to } 10 \text{ Hz}$ Equivalent input noise current  Unity-gain bandwidth  See Figure 3	Slew rate at unity gain $V_{O} = 1 \text{V to 3 V},  \text{See Figure 1}  \frac{25^{\circ}\text{C}}{\text{Full range}}$ Equivalent input noise voltage (see Figure 2) $f = 10 \text{ Hz} \qquad 25^{\circ}\text{C}$ (see Figure 2) $f = 1 \text{ kHz} \qquad 25^{\circ}\text{C}$ Peak-to-peak equivalent input noise voltage $f = 0.1 \text{ to 1 Hz} \qquad 25^{\circ}\text{C}$ Equivalent input noise current $f = 0.1 \text{ to 10 Hz} \qquad 25^{\circ}\text{C}$ Unity-gain bandwidth $See \text{ Figure 3} \qquad 25^{\circ}\text{C}$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Slew rate at unity gain $V_{O} = 1 \text{V to 3 V},  \text{See Figure 1}  \begin{array}{c} 25^{\circ}\text{C} & 0.45 & 0.65 \\ \hline \text{Full range} & 0.45 \\ \hline \text{Full range} & 0.$	PARAMETERTEST CONDITIONS $T_A^{\dagger}$ MINTYPMAXMINSlew rate at unity gain $V_0 = 1V \text{ to } 3 \text{ V}$ ,	PARAMETER         TEST CONDITIONS $T_A^{\dagger}$ MIN         TYP         MAX         MIN         0.45         D.42           Equivalent input noise current         FIGURE 3         25°C         0.16         0.09           Unity-gain bandwidth         See Figure 3         25°C         0.09         0.09	PARAMETER         TEST CONDITIONS $T_A^{\dagger}$ MIN         TYP         MAX         MIN         TYP         MAX           Slew rate at unity gain $V_O = 1V \text{ to } 3 \text{ V}$ , $V_O = 1V  $	PARAMETER         TEST CONDITIONS $T_A^{\dagger}$ MIN         TYP         MAX         MIN         0.45         0.45         0.45           Equivalent input noise current         f = 10 Hz         25°C         0.16         0.16         0.16         0.16         0.16         0.16         0.47         0.47         0.47         Equivalent input noise current         25°C         0.09         0.09         0.09         0.09         0.09         0.09         0.09         0.09         0.09         0.09         0.09         0.09         0.09         0.09         0.09		

<sup>†</sup> Full range is 0°C to 70°C for the C-suffix devices, -40°C to 85°C for the I-suffix devices, and -55°C to 125°C for the M-suffix devices.

## TLE2022 operating characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

	DADAMETED	TEST COMPITIONS	С	SUFFIX	ζ ,	1'	SUFFIX	( '	M	I SUFFIX	(	
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	V <sub>O</sub> = 1 V to 3 V, See Figure 1		0.5	'		0.5			0.5		V/μs
	Equivalent input noise voltage	f = 10 Hz		21	50		21	50		21		nV/√ <del>Hz</del>
V <sub>n</sub>	(see Figure 2)	f = 1 kHz		17	30		17	30		17		nv/∀Hz
	Deal to each aminolanting desire college	f = 0.1 to 1 Hz		0.16			0.16			0.16		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 to 10 Hz		0.47			0.47			0.47		μV
In	Equivalent input noise current			0.1			0.1			0.1	'	pA/√ <del>Hz</del>
B <sub>1</sub>	Unity-gain bandwidth	See Figure 3		1.7			1.7			1.7		MHz
$\phi_{m}$	Phase margin at unity gain	See Figure 3		47°			47°			47°		

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## TLE2022 operating characteristics at specified free-air temperature, $V_{CC}$ = $\pm 15~V$

	PARAMETER	TEST CON	IDITIONS	_	С	SUFFIX	t	1:	SUFFIX	t	М	SUFFIX	t	LINUT
	PARAMETER	TEST CON	IDITIONS	TA	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
0.0	0		0 5 1	25°C	0.45	0.65		0.45	0.65		0.45	0.65		
SR	Slew rate at unity gain	$V_0 = \pm 10 \text{ V},$	See Figure 1	Full range	0.45			0.42			0.4			V/μs
.,	Equivalent input noise	f = 10 Hz		25°C		19	50		19	50		19		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
$V_n$	voltage (see Figure 2)	f = 1 kHz		25°C		15	30		15	30		15		nV/√Hz
.,	Peak-to-peak equivalent	f = 0.1 to 1 Hz		25°C		0.16			0.16			0.16		.,
$V_{N(PP)}$	input noise voltage	f = 0.1 to 10 Hz		25°C		0.47			0.47			0.47		μV
In	Equivalent input noise current			25°C		0.1			0.1			0.1		pA/√ <del>Hz</del>
B <sub>1</sub>	Unity-gain bandwidth	See Figure 3		25°C		2.8			2.8			2.8		MHz
φ <sub>m</sub>	Phase margin at unity gain	See Figure 3		25°C		52°			52°			52°		

<sup>†</sup> Full range is 0°C to 70°C for the C-suffix devices, -40°C to 85°C for the I suffix devices and -55°C to 125°C for the I-suffix devices.

## TLE2024 operating characteristics, $V_{CC}$ = 5 V, $T_A$ = 25°C

	DADAMETER	TEST CONDITIONS	С	SUFFIX	(	19	SUFFIX		М	SUFFIX		LINUT
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	V <sub>O</sub> = 1 V to 3 V, See Figure 1		0.5			0.5			0.5		V/μs
, , , , , , , , , , , , , , , , , , ,	Facilitates transfer college (and Figure 0)	f = 10 Hz		21	50		21	50		21		nV/√ <del>Hz</del>
V <sub>n</sub>	Equivalent input noise voltage (see Figure 2)	f = 1 kHz		17	30		17	30		17		IIV/ √ ⊓Z
.,	Barbara da	f = 0.1 to 1 Hz		0.16			0.16			0.16		.,
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 to 10 Hz		0.47			0.47			0.47		μV
In	Equivalent input noise current			0.1			0.1			0.1		pA/√ <del>Hz</del>
B <sub>1</sub>	Unity-gain bandwidth	See Figure 3		1.7			1.7			1.7		MHz
φ <sub>m</sub>	Phase margin at unity gain	See Figure 3		47°			47°			47°		

## TLE2024 operating characteristics at specified free-air temperature, $V_{CC}$ = $\pm 15$ V (unless otherwise noted)

	DADAMETED	TEGT COMPLETIONS		C	SUFFIX	t	17	SUFFIX†	ī	М	SUFFIX	<u>,</u> †	
	PARAMETER	TEST CONDITIONS	T <sub>A</sub>	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
O.D.	Oleverate at main main	V 140 V Con Figure 4	25°C	0.45	0.7		0.45	0.7		0.45	0.7		\//
SR	Slew rate at unity gain	$V_O = \pm 10 \text{ V}$ , See Figure 1	Full range	0.45			0.42			0.4			V/μs
Ţ,	Equivalent input noise voltage	f = 10 Hz	25°C		19	50		19	50	1	19		
V <sub>n</sub>	(see Figure 2)	f = 1 kHz	25°C		15	30		15	30	1	15		nV/√ <del>Hz</del>
,,	Peak-to-peak equivalent input noise	f = 0.1 to 1 Hz	25°C		0.16	7	1	0.16		1	0.16		
$V_{N(PP)}$	voltage	f = 0.1 to 10 Hz	25°C		0.47	1	ĺ	0.47		1	0.47		μV
In	Equivalent input noise current	1	25°C		0.1	1	ĺ	0.1		1	0.1		pA/√ <del>Hz</del>
B <sub>1</sub>	Unity-gain bandwidth	See Figure 3	25°C		2.8	1	ĺ	2.8		1	2.8		MHz
φ <sub>m</sub>	Phase margin at unity gain	See Figure 3	25°C		52°	1		52°			52°		

<sup>†</sup> Full range is 0°C to 70°C for the C-suffix devices, -40°C to 85°C for the I suffix devices and -55°C to 125°C for the I-suffix devices.

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## TLE2021Y electrical characteristics at $V_{CC}$ = 5 V, $T_A$ = 25°C (unless otherwise noted)

	DADAMETER	TEOT COM	NITION O	Τι	E2021Y	,	
	PARAMETER	TEST COND	DITIONS	MIN	TYP	MAX	UNIT
$V_{IO}$	Input offset voltage				150		μV
	Input offset voltage long-term drift (see Note 4)	., .	D 500		0.005		μV/mo
I <sub>IO</sub>	Input offset current	$V_{IC} = 0,$	$R_S = 50 \Omega$		0.5		nA
I <sub>IB</sub>	Input bias current				35		nA
V <sub>ICR</sub>	Common-mode input voltage range	R <sub>S</sub> = 50 Ω			- 0.3 to 4		٧
V <sub>OH</sub>	Maximum high-level output voltage	D 4010			4.3		V
$V_{OL}$	Maximum low-level output voltage	$R_L = 10 \text{ k}\Omega$			0.7		V
$A_{VD}$	Large-signal differential voltage amplification	$V_0 = 1.4 \text{ to } 4 \text{ V},$	$R_L = 10 \text{ k}\Omega$		1.5		V/µV
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR} min,$	$R_S = 50 \Omega$		100		dB
k <sub>SVR</sub>	Supply-voltage rejection ratio ( $\Delta V_{CC\pm}/\Delta V_{IO}$ )	$V_{CC} = 5 \text{ V to } 30 \text{ V}$			115		dB
I <sub>CC</sub>	Supply current	V <sub>O</sub> = 2.5 V,	No load		400		μА

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^{\circ}$ C extrapolated to  $T_A = 25^{\circ}$ C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

# TLE2021Y operating characteristics at $V_{CC}$ = 5 V, $T_A$ = 25°C

	242445	TEGT COMPLETIONS	TL	E2021Y	,	
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	V <sub>O</sub> = 1 V to 3 V		0.5		V/μs
	Facility along the same and the same	f = 10 Hz		21		nV/√ <del>Hz</del>
V <sub>n</sub>	Equivalent input noise voltage	f = 1 kHz		17		IIV/∀⊓Z
.,	Dools to cools on the least insert action with the	f = 0.1 to 1 Hz		0.16		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 to 10 Hz		0.47		μV
In	Equivalent input noise current			0.1		pA/√ <del>Hz</del>
B <sub>1</sub>	Unity-gain bandwidth			1.7		MHz
φ <sub>m</sub>	Phase margin at unity gain			47°		

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## TLE2022Y electrical characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

	DADAMETED	TEGT COM	NITIONIO.	TL	E2022Y		
	PARAMETER	TEST COND	DITIONS	MIN	TYP	MAX	UNIT
$V_{IO}$	Input offset voltage				150	600	μV
	Input offset voltage long-term drift (see Note 4)	],, ,	D 500		0.005		μV/mo
I <sub>IO</sub>	Input offset current	$V_{IC} = 0,$	$R_S = 50 \Omega$		0.5		nA
I <sub>IB</sub>	Input bias current				35		nA
V <sub>ICR</sub>	Common-mode input voltage range	R <sub>S</sub> = 50 Ω			- 0.3 to 4		٧
V <sub>OH</sub>	Maximum high-level output voltage	5 4010			4.3		V
V <sub>OL</sub>	Maximum low-level output voltage	$R_L = 10 \text{ k}\Omega$			0.7		V
$A_{VD}$	Large-signal differential voltage amplification	V <sub>O</sub> = 1.4 to 4 V,	R <sub>L</sub> = 10 kΩ		1.5		V/µV
CMRR	Common-mode rejection ratio	V <sub>IC</sub> = V <sub>ICR</sub> min,	$R_S = 50 \Omega$		100		dB
k <sub>SVR</sub>	Supply-voltage rejection ratio ( $\Delta V_{CC\pm}/\Delta V_{IO}$ )	$V_{CC} = 5 \text{ V to } 30 \text{ V}$			115		dB
I <sub>CC</sub>	Supply current	V <sub>O</sub> = 2.5 V,	No load		450		μΑ

NOTE 4: Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150$ °C extrapolated to  $T_A = 25$ °C using the Arrhenius equation and assuming an activation energy of 0.96 eV.

# TLE2022Y operating characteristics, $V_{CC}$ = 5 V, $T_A$ = 25°C

	DADAMETED	TEST COMPITIONS	TLE2022Y	
	PARAMETER	TEST CONDITIONS	MIN TYP MAX	UNIT
SR	Slew rate at unity gain	V <sub>O</sub> = 1 V to 3 V, See Figure 1	0.5	V/μs
.,	For industries tracing allows (see Fig. 19.0)	f = 10 Hz	21	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
V <sub>n</sub>	Equivalent input noise voltage (see Figure 2)	f = 1 kHz	17	nV/√ <del>Hz</del>
V	Prof. to cont. or industrial toward allows	f = 0.1 to 1 Hz	0.16	.,
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 to 10 Hz	0.47	μV
In	Equivalent input noise current		0.1	pA/√ <del>Hz</del>
B <sub>1</sub>	Unity-gain bandwidth	See Figure 3	1.7	MHz
φm	Phase margin at unity gain	See Figure 3	47°	

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# TLE2024Y electrical characteristics, $V_{CC}$ = 5 V, $T_A$ = 25°C (unless otherwise noted)

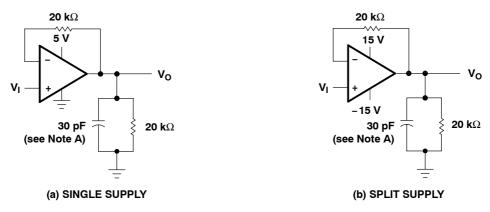
	DADAMETED	TEST SOUR	TIONO	TL	E2024Y	,	
	PARAMETER	TEST CONDI	HONS	MIN	TYP	MAX	UNIT
	Input offset voltage long-term drift (see Note 4)				0.005		μV/mo
I <sub>IO</sub>	Input offset current	$V_{IC} = 0$ ,	$R_S = 50 \Omega$		0.6		nA
I <sub>IB</sub>	Input bias current				45		nA
V <sub>ICR</sub>	Common-mode input voltage range	R <sub>S</sub> = 50 Ω			-0.3 to 4		٧
V <sub>OH</sub>	High-level output voltage	D 4010			4.2		V
$V_{OL}$	Low-level output voltage	$R_L = 10 \text{ k}\Omega$			0.7		V
A <sub>VD</sub>	Large-signal differential voltage amplification	V <sub>O</sub> = 1.4 V to 4 V,	$R_L = 10 \text{ k}\Omega$		1.5		V/μV
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}min,$	$R_S = 50 \Omega$		90		dB
kSVR	Supply-voltage rejection ratio $(\Delta V_{CC}/\Delta V_{IO})$	V <sub>CC</sub> = 5 V to 30 V	_		112		dB
I <sub>CC</sub>	Supply current	$V_0 = 2.5 V$ ,	No load		800		μΑ

NOTE 4. Typical values are based on the input offset voltage shift observed through 168 hours of operating life test at  $T_A = 150^{\circ}C$  extrapolated to  $T_A = 25^{\circ}C$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

# TLE2024Y operating characteristics, $V_{CC}$ = 5 V, $T_A$ = 25°C

PARAMETER		TEST CONDITIONS		TLE2024Y				
				MIN	TYP	MAX	UNIT	
SR	Slew rate at unity gain	$V_O = 1 \text{ V to 3 V}$ , See	Figure 1		0.5		V/μs	
V <sub>n</sub>	Equivalent input noise voltage (see Figure 2)	f = 10 Hz			21		nV/√Hz	
		f = 1 kHz			17			
V <sub>N(PP)</sub>	Peak-to-peak equivalent input noise voltage	f = 0.1 to 1 Hz			0.16			
		f = 0.1 to 10 Hz			0.47		μV	
In	Equivalent input noise current				0.1		pA/√ <del>Hz</del>	
B <sub>1</sub>	Unity-gain bandwidth	See Figure 3			1.7		MHz	
φ <sub>m</sub>	Phase margin at unity gain	See Figure 3	_		47°			

#### PARAMETER MEASUREMENT INFORMATION



NOTE A:  $C_L$  includes fixture capacitance.

Figure 1. Slew-Rate Test Circuit

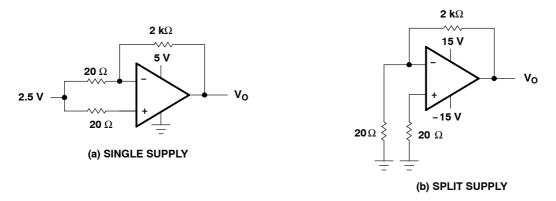
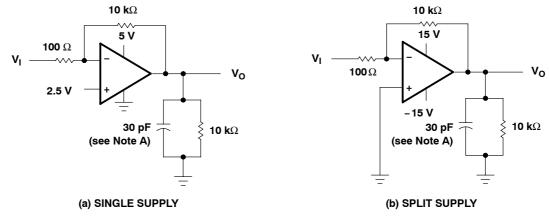


Figure 2. Noise-Voltage Test Circuit



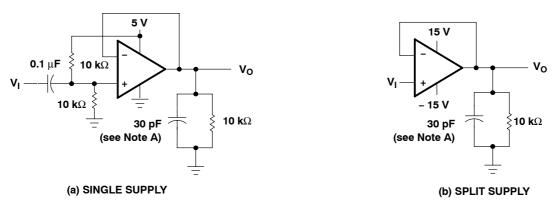
NOTE A: C<sub>L</sub> includes fixture capacitance.

Figure 3. Unity-Gain Bandwidth and Phase-Margin Test Circuit

# TLE202xA, TLE202xB, TLE202xY EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

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#### PARAMETER MEASUREMENT INFORMATION



NOTE A:  $C_L$  includes fixture capacitance.

Figure 4. Small-Signal Pulse-Response Test Circuit

## typical values

Typical values presented in this data sheet represent the median (50% point) of device parametric performance.



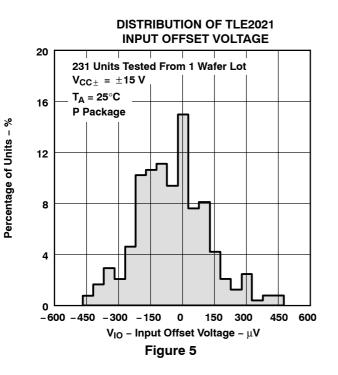
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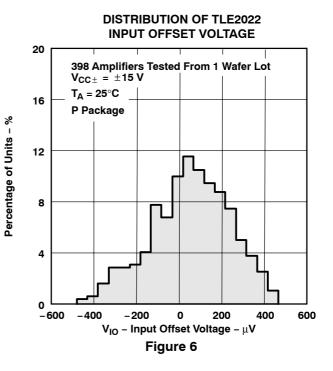
### **TYPICAL CHARACTERISTICS**

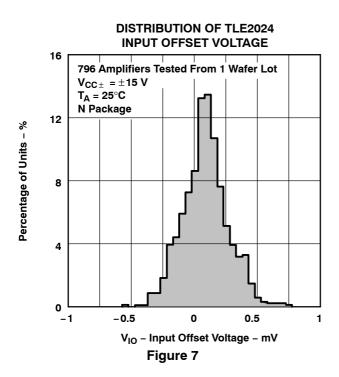
## **Table of Graphs**

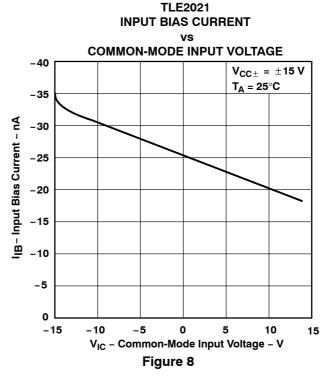
			FIGURE	
$V_{IO}$	Input offset voltage	Distribution	5, 6, 7	
I <sub>IB</sub>	Input bias current	vs Common-mode input voltage vs Free-air temperature	8, 9, 10 11, 12, 13	
I <sub>I</sub>	Input current	vs Differential input voltage	14	
$V_{OM}$	Maximum peak output voltage	vs Output current vs Free-air temperature	15, 16, 17 18	
V <sub>OH</sub>	High-level output voltage	vs High-level output current vs Free-air temperature	19, 20 21	
V <sub>OL</sub>	Low-level output voltage	vs Low-level output current vs Free-air temperature	22 23	
V <sub>O(PP)</sub>	Maximum peak-to-peak output voltage	vs Frequency	24, 25	
$A_{VD}$	Large-signal differential voltage amplification	vs Frequency vs Free-air temperature	26 27, 28, 29	
Ios	Short-circuit output current	vs Supply voltage vs Free-air temperature	30 - 33 34 - 37	
I <sub>CC</sub>	Supply current	vs Supply voltage vs Free-air temperature	38, 39, 40 41, 42, 43	
CMRR	Common-mode rejection ratio	vs Frequency	44, 45, 46	
SR	Slew rate	vs Free-air temperature	47, 48, 49	
	Voltage-follower small-signal pulse response		50, 51	
	Voltage-follower large-signal pulse response		52 – 57	
V <sub>N(PP)</sub>	Peak-to-peak equivalent input noise voltage	0.1 to 1 Hz 0.1 to 10 Hz	58 59	
V <sub>n</sub>	Equivalent input noise voltage	vs Frequency	60	
B <sub>1</sub>	Unity-gain bandwidth	vs Supply voltage vs Free-air temperature	61, 62 63, 64	
φ <sub>m</sub>	Phase margin	vs Supply voltage vs Load capacitance vs Free-air temperature	65, 66 67, 68 69, 70	
	Phase shift	vs Frequency	26	

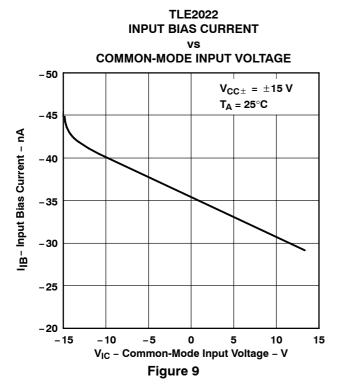
#### TYPICAL CHARACTERISTICS

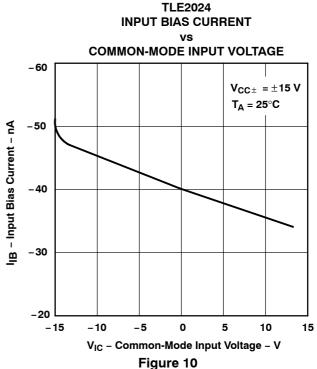


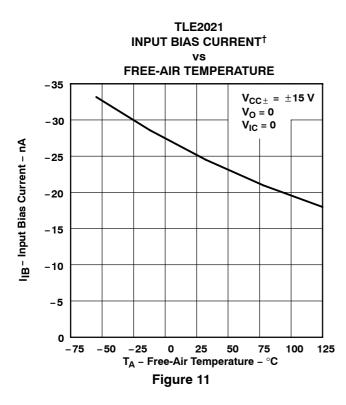


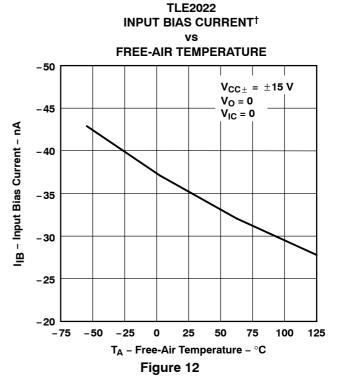






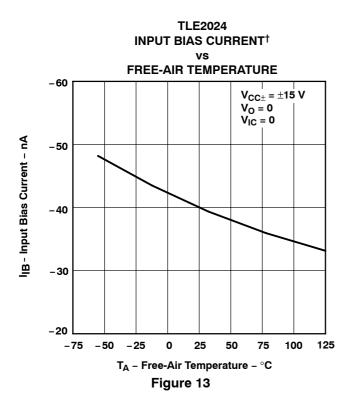






<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.





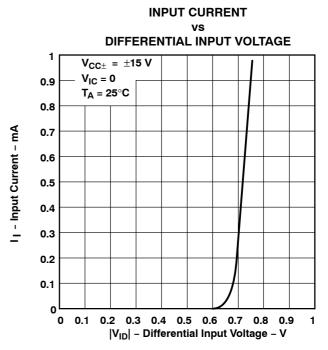
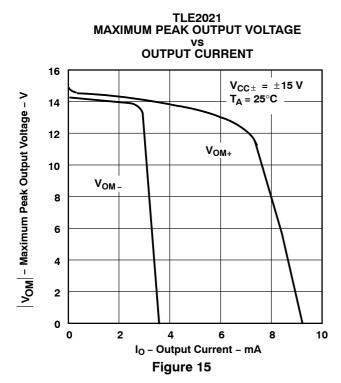
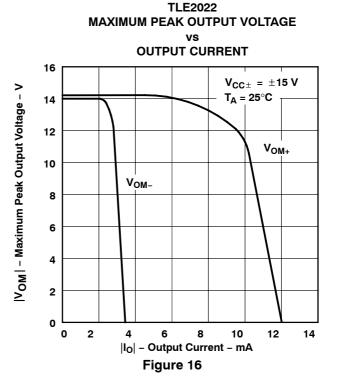


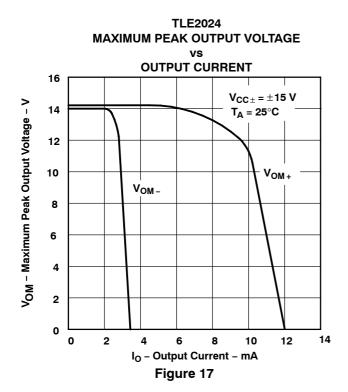
Figure 14

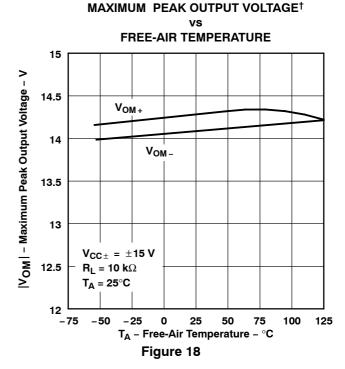




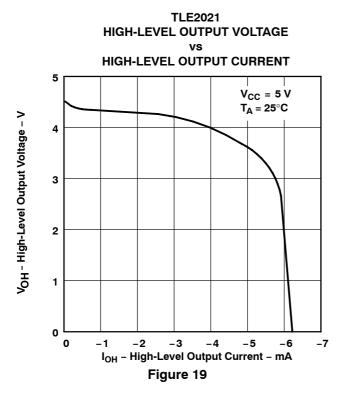
<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

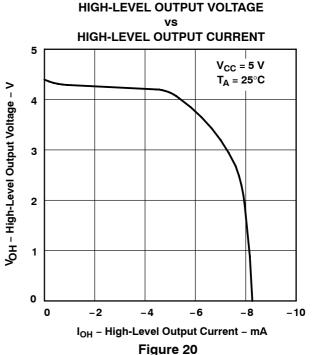






**TLE2022 AND TLE2024** 



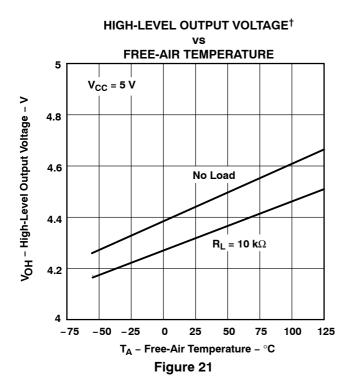


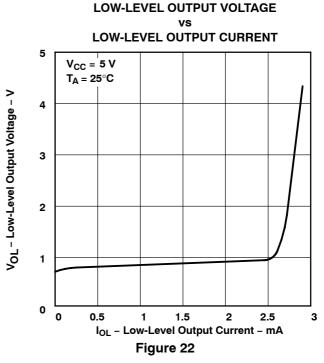
<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

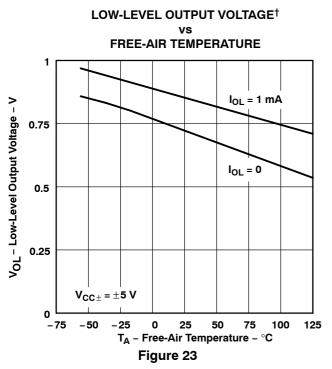


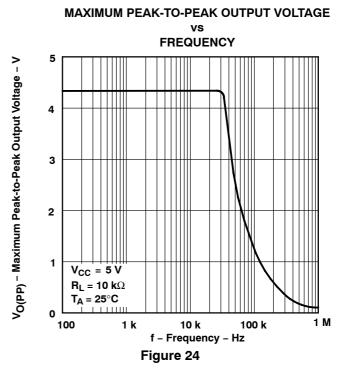
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#### TYPICAL CHARACTERISTICS









<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



#### **MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE**

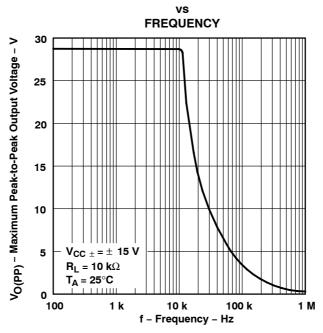


Figure 25

# LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT

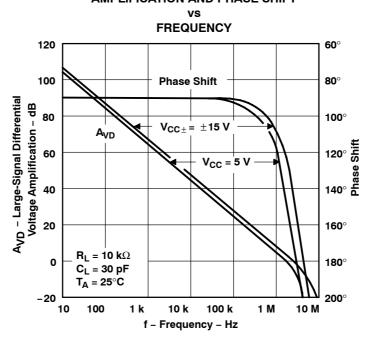


Figure 26

1

-75

-50

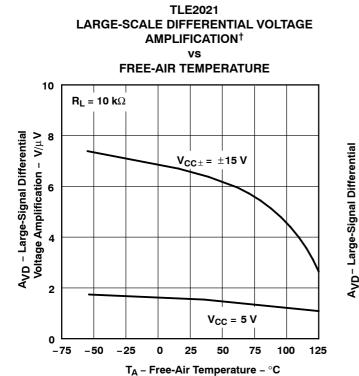
-25

0

25

 $T_A$  – Free-Air Temperature –  $^{\circ}C$ 

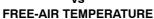
Figure 28

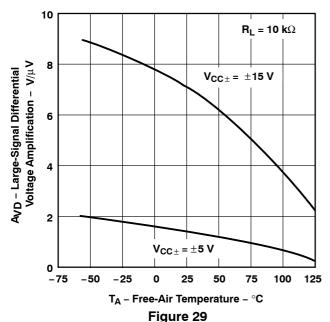


**TLE2022** 

TLE2024
LARGE-SCALE DIFFERENTIAL VOLTAGE
AMPLIFICATION†
vs

Figure 27





# TLE2021 SHORT-CIRCUIT OUTPUT CURRENT vs SUPPLY VOLTAGE

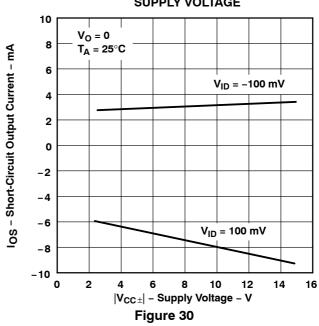
V<sub>CC</sub> = 5 V

75

100

125

50



 $<sup>^\</sup>dagger$  Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



TLE2021

#### **TYPICAL CHARACTERISTICS**

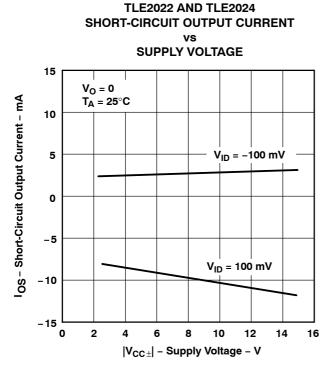
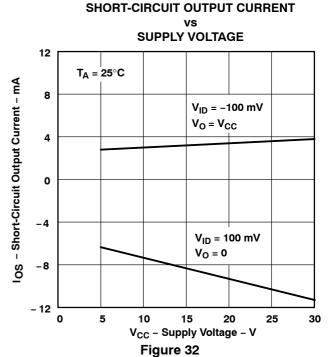
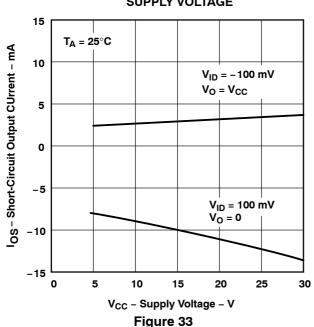


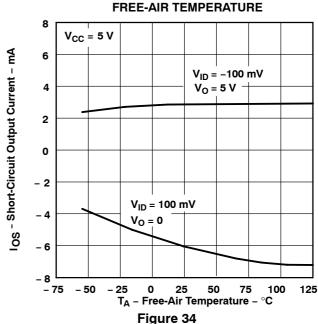
Figure 31



TLE2022 AND TLE2024
SHORT-CIRCUIT OUTPUT CURRENT
vs
SUPPLY VOLTAGE

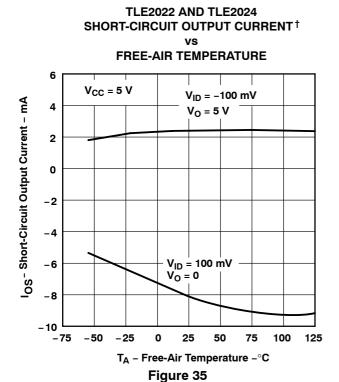


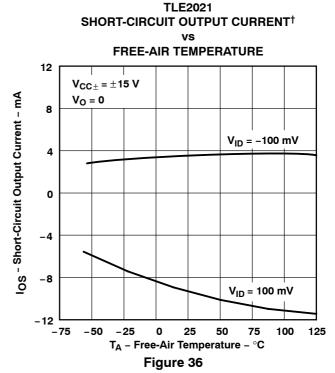
# TLE2021 SHORT-CIRCUIT OUTPUT CURRENT† vs

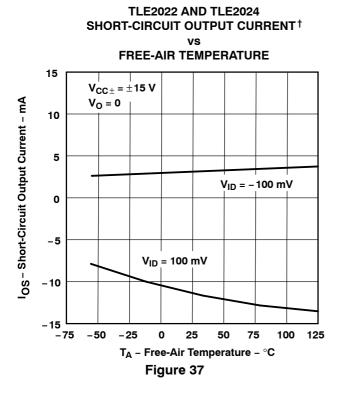


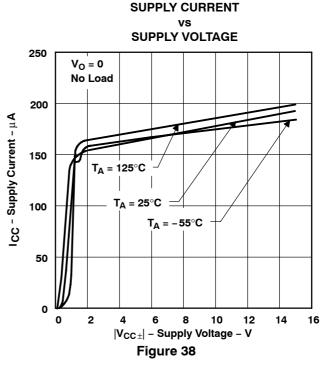
<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.







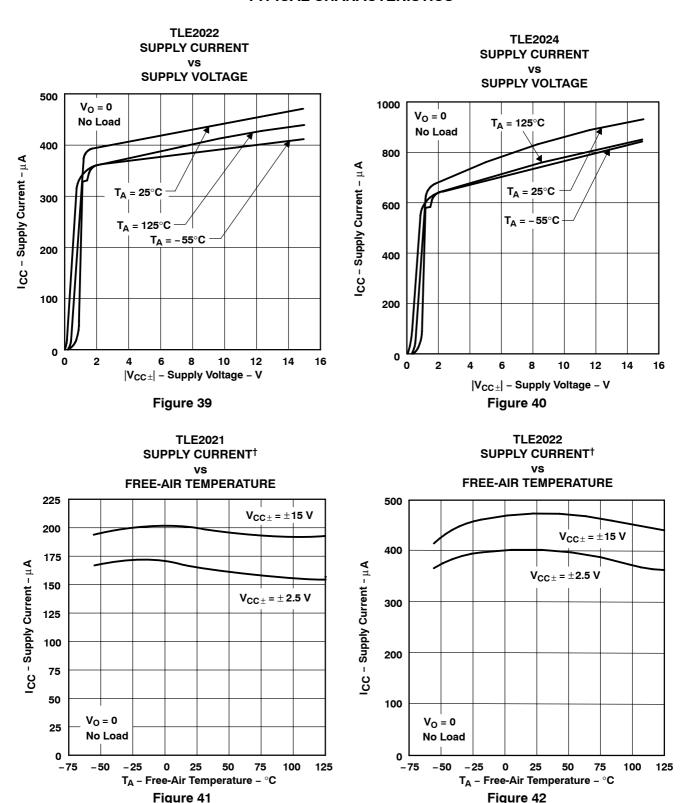




TLE2021

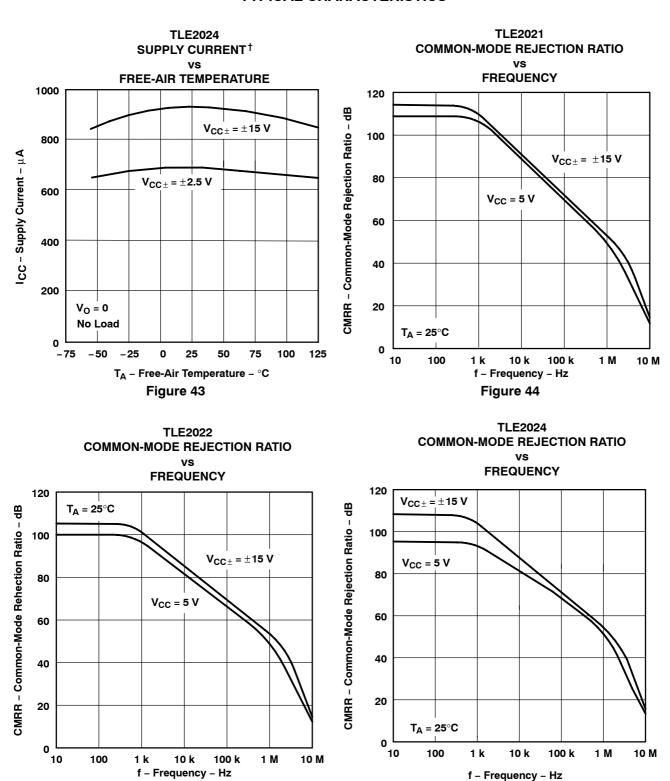
<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.





<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



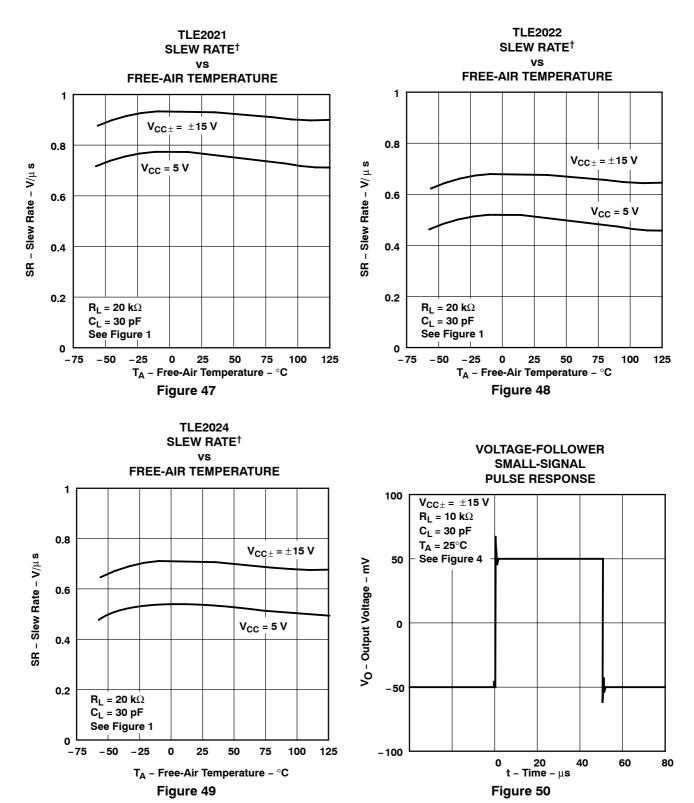


<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

Figure 45

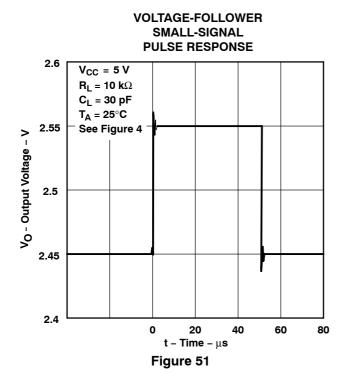


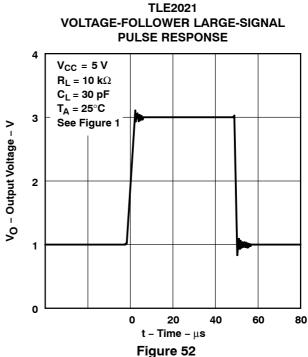
Figure 46



<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

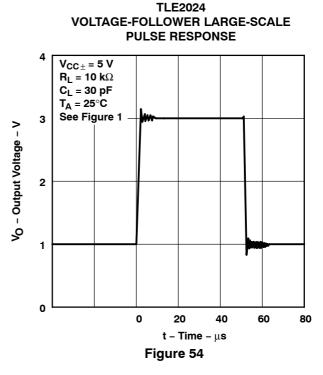






**VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE** V<sub>CC</sub> = 5 V  $R_L = 10 \text{ k}\Omega$ C<sub>L</sub> = 30 pF T<sub>A</sub> = 25°C See Figure 1 3 V<sub>O</sub> - Output Voltage - V 1 0 20 60 80  $\textbf{t-Time}-\mu\textbf{s}$ Figure 53

**TLE2022** 



#### TLE2021 VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

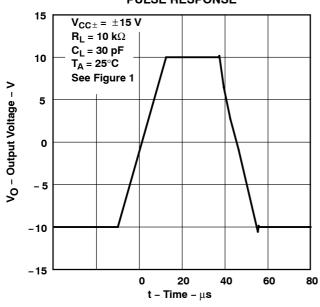
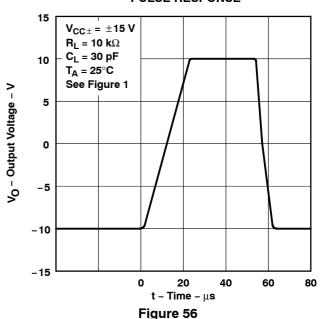


Figure 55

#### TLE2022 VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE



TLE2024 VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

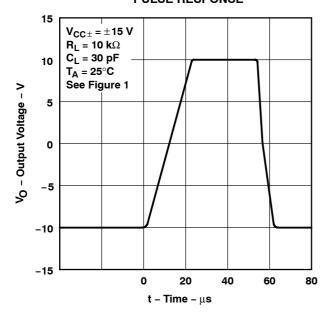
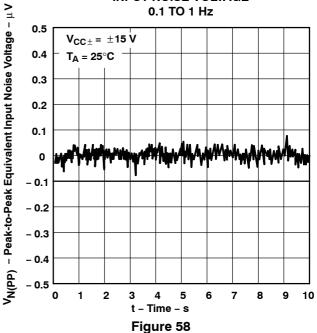
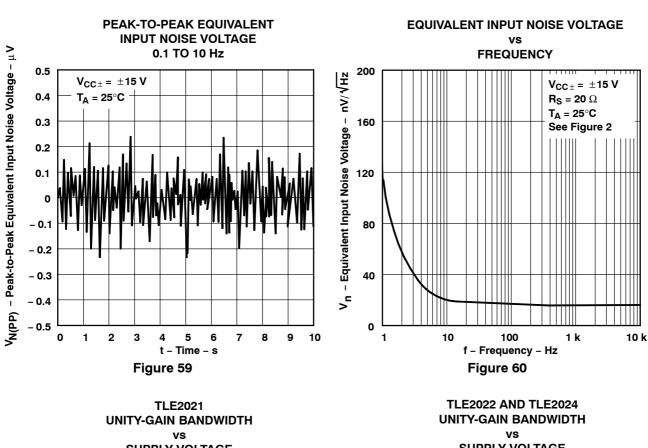
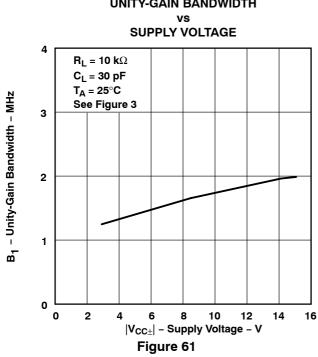


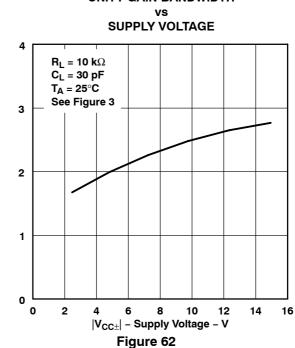
Figure 57

# PEAK-TO-PEAK EQUIVALENT INPUT NOISE VOLTAGE

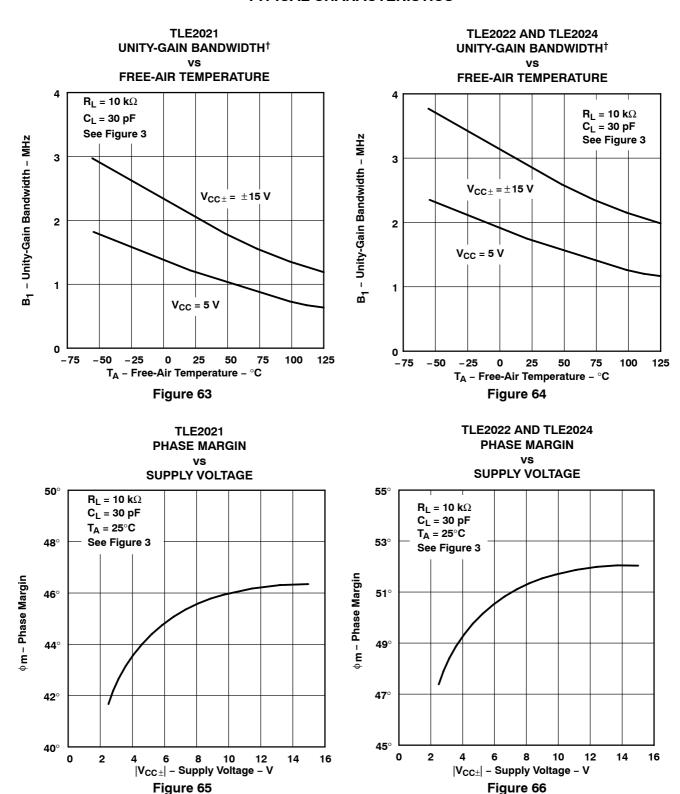






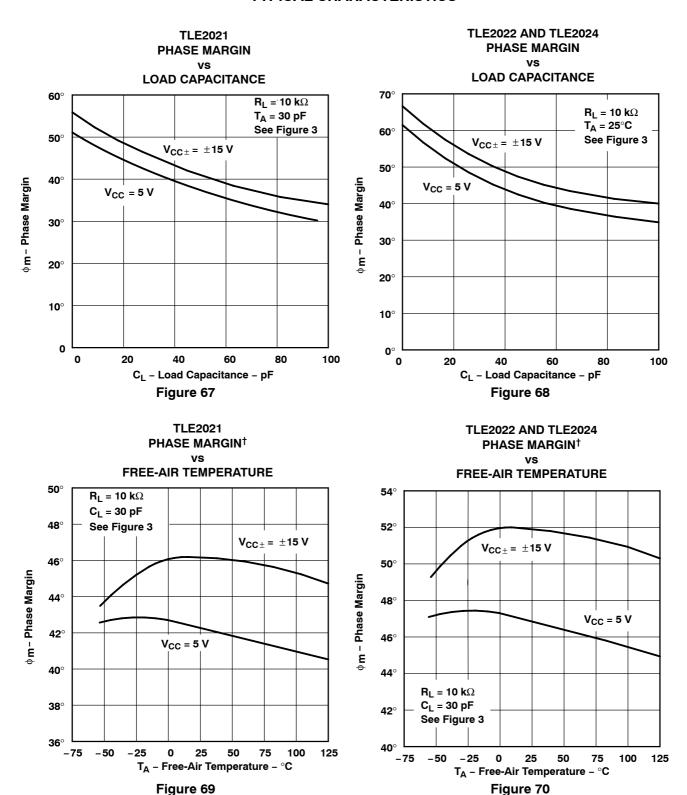


B<sub>1</sub> - Unity-Gain Bandwidth - MHz



 $<sup>^\</sup>dagger$  Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.





<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



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#### **APPLICATION INFORMATION**

#### voltage-follower applications

The TLE202x circuitry includes input-protection diodes to limit the voltage across the input transistors; however, no provision is made in the circuit to limit the current if these diodes are forward biased. This condition can occur when the device is operated in the voltage-follower configuration and driven with a fast, large-signal pulse. It is recommended that a feedback resistor be used to limit the current to a maximum of 1 mA to prevent degradation of the device. This feedback resistor forms a pole with the input capacitance of the device. For feedback resistor values greater than  $10 \text{ k}\Omega$ , this pole degrades the amplifier phase margin. This problem can be alleviated by adding a capacitor (20 pF to 50 pF) in parallel with the feedback resistor (see Figure 71).

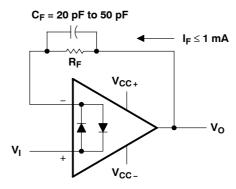


Figure 71. Voltage Follower

#### Input offset voltage nulling

The TLE202x series offers external null pins that further reduce the input offset voltage. The circuit in Figure 72 can be connected as shown if this feature is desired. When external nulling is not needed, the null pins may be left disconnected.

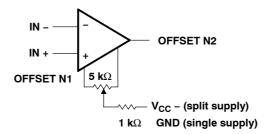


Figure 72. Input Offset Voltage Null Circuit

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#### **APPLICATION INFORMATION**

#### macromodel information

Macromodel information provided was derived using Microsim *Parts*™, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 5) and subcircuit in Figure 73, Figure 74, and Figure 75 were generated using the TLE202x typical electrical and operating characteristics at 25°C. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification

- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 5: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

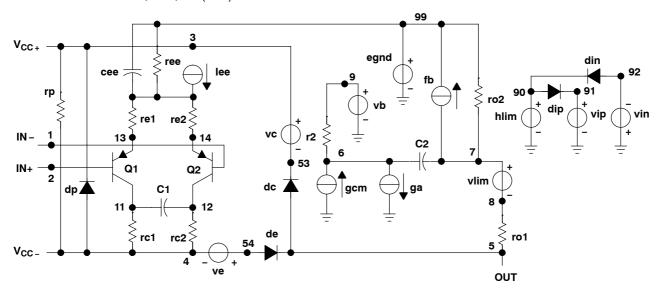


Figure 73. Boyle Subcircuit

PSpice and Parts are trademarks of MicroSim Corporation.



#### TLE202x, TLE202xA, TLE202xB, TLE202xY EXCALIBUR HIGH-SPEED LOW-POWER PRECISION OPERATIONAL AMPLIFIERS

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```
.SUBCKT TLE2021 12345
                                                                             poly(2) vcm+ vcm- 0 1E2 1E2
                                                                hcmr 80
                                                                      3
                                                                          4
                                                                              185E-6
            12 6.244E-12
 с1
        11
                                                                      3
                                                                          10 dc 15.67E-6
                                                                iee
 c2
        6
            7 13.4E-12
                                                                             2F-9
                                                                iio
                                                                      2
                                                                          0
            0 10.64E-9
 сЗ
        87
                                                                      88
                                                                         0
                                                                             1E-21
            86 15.9E-9
       85
 cosr
                                                                      11
                                                                          89 13 qx
                                                                q1
 dcm+ 81
            82 dx
                                                                q2
                                                                      12
                                                                          80
                                                                             14 qx
 dcm- 83
            81 dx
                                                                Ŕ2
                                                                      6
                                                                             100.0E3
 dc
        5
            53 dx
                                                                      84
                                                                          81 1K
                                                                rcm
        54 5 dx
                                                                ree
                                                                      10
                                                                          99
                                                                             14.76E6
 qlb
        90
            91 dx
                                                                rn1
                                                                      87
                                                                          0
                                                                             2.55E8
 dln
        92
            90 dx
                                                                          88 11.67E3
                                                                rn2
                                                                      87
        4
 dp
            3 dx
                                                                ro1
                                                                      8
                                                                          5
                                                                             62
 ecmr 84
            99 (2 99) 1
                                                                ro2
                                                                      7
                                                                          99 63
 egnd
       99
            0 poly(2) (3,0) (4,0) 0 .5 .5
                                                                vcm+ 82
                                                                          99 13.3
 epsr
            0 poly(1) (3,4) -60E-6 2.0E-6
                                                                vcm- 83
                                                                          99
                                                                             -14.6
            2 poly(1) (88,0) 120E-6 1
 ense 89
                                                                vh
                                                                      9
                                                                          0 dc 0
 fb
            99 poly(6) vb vc ve vlp vln vpsr 0 547.3E6
                                                                VC
                                                                      3
                                                                          53 dc 1.300
 + -50E7 50E7 50E7 -50E7 547E6
                                                                ve
                                                                      54
                                                                          4
                                                                             dc 1.500
 ga
        6
            0 11 12 188.5E-6
                                                                vlim 7
                                                                          8
                                                                             dc 0
 gcm
        0
            6 10 99 335.2E-12
                                                                vlp
                                                                      91
                                                                          0
                                                                             dc 3.600
       85 86 (85,86) 100E-6
 gpsr
                                                                vln
                                                                      0
                                                                          92 dc 3.600
 grc1
       4
            11 (4,11) 1.885E-4
                                                                vpsr 0
                                                                          86 dc 0
            12 (4,12) 1.885E-4
 grc2
                                                              .model dx d(is=800.0E-18)
       13 10 (13,10) 6.82E-4
 gre1
                                                              .model qx pnp(is=800.0E-18 bf=270)
 gre2
       14 10 (14,10) 6.82E-4
       90 0 vlim 1k
 hlim
```

Figure 74. Boyle Macromodel for the TLE2021

```
.SUBCKT TLE2022 1 2 3 4 5
                                                               11 2.842E3
                                                            4
                                                               12 2.842E3
                                                       rc2
 c1
       11 12 6.814E-12
                                                       ge1 13 10 (10,13) 31.299E-3
 c2
          7 20.00E-12
                                                               10 (10,14) 31.299E-3
                                                       ge2
                                                            14
 dc
          53 dx
                                                           10 99 11.07E6
                                                       ree
       54 5 dx
 de
                                                       rol 8
                                                               5 250
     90 91 dx
 dlp
                                                               99 250
                                                       ro2
 dln 92 90 dx
                                                               4 137.2E3
                                                            3
                                                       rp
       4
          3 dx
 dр
                                                       vb
                                                            9
                                                               0 dc 0
 egnd 99
          0 poly(2) (3,0) (4,0) 0 .5 .5
                                                       VC
                                                            3
                                                               53 dc 1.300
 fb
      7
          99 poly(5) vb vc ve vlp vln 0
                                                            54 4 dc 1.500
                                                       ve
 45.47E6 -50E6 50E6 50E6 -50E6
                                                       vlim 7
                                                               8 dc 0
 ga 6 0
          11 12 377.9E-6
                                                       vlp 91 0 dc 3
 gcm 0 6
          10 99 7.84E-10
                                                       vln 0
                                                               92 dc 3
          10 DC 18.07E-6
 iee 3
                                                     .model dx d(is=800.0E-18)
 hlim 90
          0 vlim 1k
                                                     .model qx pnp(is=800.0E-18 bf=257.1)
      11 2 13 qx
 q1
                                                      .ends
       12 1 14 qx
 q2
          9 100.0E3
 r2
       6
```

Figure 75. Boyle Macromodel for the TLE2022





8-Jun-2017

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	(1)					(2)	(6)	(3)		` '	
5962-9088101MPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9088101MPA TLE2021M	Sample
5962-9088102M2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088102M2A TLE2022MFKB	Sample
5962-9088102MPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9088102MPA TLE2022M	Sample
5962-9088103M2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088103M2A TLE2024MFKB	Sample
5962-9088103MCA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9088103MC A TLE2024MJB	Samples
5962-9088104Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088104Q2A TLE2021 AMFKB	Samples
5962-9088104QPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9088104QPA TLE2021AM	Samples
5962-9088105Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088105Q2A TLE2022A MFKB	Samples
5962-9088105QPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9088105QPA TLE2022AM	Samples
5962-9088106Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088106Q2A TLE2024A MFKB	Samples
5962-9088106QCA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9088106QC A TLE2024AMJB	Samples
5962-9088107Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088107Q2A TLE2021 BMFKB	Samples



Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9088107QPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9088107QPA TLE2021BM	Samples
5962-9088108Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088108Q2A TLE2022B MFKB	Samples
5962-9088108QPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9088108QPA TLE2022BM	Samples
5962-9088109Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088109Q2A TLE2024 BMFKB	Samples
5962-9088109QCA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9088109QC A TLE2024BMJB	Samples
TLE2021ACD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2021AC	Samples
TLE2021ACDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2021AC	Samples
TLE2021ACDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2021AC	Samples
TLE2021ACDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2021AC	Samples
TLE2021ACP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2021AC	Samples
TLE2021ACPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2021AC	Samples
TLE2021AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2021AI	Samples
TLE2021AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2021AI	Samples
TLE2021AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2021AI	
TLE2021AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2021AI	Samples
TLE2021AIP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2021AI	Samples



Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TLE2021AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088104Q2A TLE2021 AMFKB	Samples
TLE2021AMJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9088104QPA TLE2021AM	Samples
TLE2021BMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type		5962- 9088107Q2A TLE2021 BMFKB	Sample
TLE2021BMJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	TLE2021 BMJG	Samples
TLE2021BMJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type		9088107QPA TLE2021BM	Sample
TLE2021CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2021C	Sample
TLE2021CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2021C	Sample
TLE2021CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2021C	Sample
TLE2021CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2021C	Sample
TLE2021CP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLE2021CP	Sample
TLE2021CPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLE2021CP	Sample
TLE2021ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	20211	Sample
TLE2021IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	20211	Sample
TLE2021IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	20211	Sample
TLE2021IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	20211	Sample
TLE2021IP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TLE2021IP	Sample



Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TLE2021IPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TLE2021IP	Samples
TLE2021MD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	2021M	Samples
TLE2021MDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2021M	Samples
TLE2021MJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	TLE2021MJG	Samples
TLE2021MJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9088101MPA TLE2021M	Samples
TLE2022ACD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2022AC	Samples
TLE2022ACDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2022AC	Samples
TLE2022ACDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2022AC	Samples
TLE2022ACDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2022AC	Samples
TLE2022ACP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2022AC	Samples
TLE2022ACPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2022AC	Samples
TLE2022AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2022AI	Samples
TLE2022AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2022AI	Samples
TLE2022AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2022AI	Samples
TLE2022AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2022AI	Samples
TLE2022AIP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2022AI	Sample
TLE2022AMD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	2022AM	Sample
TLE2022AMDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2022AM	Sample





Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TLE2022AMDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	2022AM	Samples
TLE2022AMDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2022AM	Samples
TLE2022AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088105Q2A TLE2022A MFKB	Samples
TLE2022AMJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9088105QPA TLE2022AM	Samples
TLE2022BMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088108Q2A TLE2022B MFKB	Samples
TLE2022BMJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9088108QPA TLE2022BM	Samples
TLE2022CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2022C	Samples
TLE2022CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2022C	Samples
TLE2022CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2022C	Samples
TLE2022CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2022C	Samples
TLE2022CP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2022CP	Samples
TLE2022CPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2022CP	Samples
TLE2022ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	20221	Samples
TLE2022IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	20221	Samples
TLE2022IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	20221	Samples
TLE2022IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2022	Samples



Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
TLE2022IP	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2022IP	Samples
TLE2022IPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2022IP	Samples
TLE2022MD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	2022M	Samples
TLE2022MDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2022M	Samples
TLE2022MDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	2022M	Samples
TLE2022MDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2022M	Samples
TLE2022MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088102M2A TLE2022MFKB	Samples
TLE2022MJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	TLE2022MJG	Samples
TLE2022MJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9088102MPA TLE2022M	Samples
TLE2024ACDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2024AC	Samples
TLE2024ACDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TLE2024AC	Samples
TLE2024ACDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2024AC	Samples
TLE2024ACN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2024ACN	Samples
TLE2024ACNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2024ACN	Samples
TLE2024AIDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLE2024AI	Samples
TLE2024AIDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	-40 to 85 TLE2024AI	
TLE2024AIN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	TLE2024AIN		Samples
TLE2024AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088106Q2A	Samples





Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking  (4/5)  TLE2024A  MFKB	Samples
TLE2024AMJB	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9088106QC A TLE2024AMJB	Sample
TLE2024BMDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	TLE2024BM	Sample
TLE2024BMDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2024BM	Samples
TLE2024BMDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	TLE2024BM	Samples
TLE2024BMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088109Q2A TLE2024 BMFKB	Samples
TLE2024BMJ	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	TLE2024BMJ	Samples
TLE2024BMJB	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9088109QC A TLE2024BMJB	Samples
TLE2024CDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2024C	Samples
TLE2024CDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2024C	Samples
TLE2024CDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2024C	Samples
TLE2024CDWRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2024C	Samples
TLE2024CN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2024CN	Samples
TLE2024CNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2024CN	Samples
TLE2024IDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2024I	Samples
TLE2024IDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2024I	Samples



#### PACKAGE OPTION ADDENDUM

8-Jun-2017

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TLE2024IN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2024IN	Samples
TLE2024MDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	TLE2024M	Samples
TLE2024MDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	TLE2024M	Samples
TLE2024MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9088103M2A TLE2024MFKB	Samples
TLE2024MJB	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9088103MC A TLE2024MJB	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



#### PACKAGE OPTION ADDENDUM

8-Jun-2017

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OTHER QUALIFIED VERSIONS OF TLE2021A, TLE2021AM, TLE2021AM, TLE2021M, TLE2022AM, TLE2022AM, TLE2022AM, TLE2022AM, TLE2022AM, TLE2024AM, TLE2024AM, TLE2024BM, TLE2024

- Catalog: TLE2021A, TLE2021, TLE2022A, TLE2022, TLE2024A, TLE2024B, TLE2024
- Automotive: TLE2021-Q1, TLE2021A-Q1, TLE2021A-Q1, TLE2021-Q1, TLE2022-Q1, TLE2022A-Q1, TLE2022A-Q1, TLE2022-Q1, TLE2022-Q1, TLE2024A-Q1, TLE2024A-Q1, TLE2024A-Q1
   TLE2024-Q1
- Enhanced Product: TLE2021-EP, TLE2021A-EP, TLE2021A-EP, TLE2021-EP, TLE2022-EP, TLE2022A-EP, TLE2022A-EP, TLE2022-EP, TLE2024-EP, TLE202
- Military: TLE2021M, TLE2021AM, TLE2022M, TLE2022AM, TLE2024AM, TLE2024AM, TLE2024BM

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

**PACKAGE MATERIALS INFORMATION** 

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#### TAPE AND REEL INFORMATION



# TAPE DIMENSIONS KO P1 BO W Cavity AO

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLE2021ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2021ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2021AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2021CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2021IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2022ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2022AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2022AMDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2022AMDRG4	SOIC	D	8	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
TLE2022CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2022CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2022IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2022MDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2024ACDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
TLE2024CDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
	<u> </u>				<u> </u>	· , ,	• • •
TLE2021ACDR	SOIC	D	8	2500	367.0	367.0	38.0
TLE2021ACDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2021AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2021CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2021IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2022ACDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2022AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2022AMDR	SOIC	D	8	2500	367.0	367.0	38.0
TLE2022AMDRG4	SOIC	D	8	2500	340.5	338.1	20.6
TLE2022CDR	SOIC	D	8	2500	367.0	367.0	38.0
TLE2022CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2022IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2022MDR	SOIC	D	8	2500	367.0	367.0	38.0
TLE2024ACDWR	SOIC	DW	16	2000	367.0	367.0	38.0
TLE2024CDWR	SOIC	DW	16	2000	367.0	367.0	38.0

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
   Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
   Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



## D (R-PDSO-G8)

#### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



# D (R-PDSO-G8)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



SMALL OUTLINE INTEGRATED CIRCUIT



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040000-2/H





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
- 5. Reference JEDEC registration MS-013.



SOIC



#### NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



#### JG (R-GDIP-T8)

#### **CERAMIC DUAL-IN-LINE**



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8

# P (R-PDIP-T8)

#### PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



### N (R-PDIP-T\*\*)

#### PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



## FK (S-CQCC-N\*\*)

#### LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



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